

**SSD1320**

*Advance Information*

**160 x 160, 16 Gray Scale Dot Matrix  
OLED/PLED Segment/Common Driver with Controller**

This document contains information on a new product. Specifications and information herein are subject to change without notice.

<http://www.solomon-systech.com>

**SSD1320** | Rev 1.0 | P 1/39 | May 2017 |

Copyright © 2017 **Solomon Systech Limited**



**Appendix: IC Revision history of SSD1320 Specification**

<b>Version</b>	<b>Change Items</b>	<b>Effective Date</b>
1.0	1 <sup>st</sup> Release	16-May-17

**Confidential to  
WiseChip Semiconductor Inc.**

## CONTENTS

<b>1</b>	<b>GENERAL DESCRIPTION</b> .....	<b>6</b>
<b>2</b>	<b>FEATURES</b> .....	<b>6</b>
<b>3</b>	<b>ORDERING INFORMATION</b> .....	<b>6</b>
<b>4</b>	<b>BLOCK DIAGRAM</b> .....	<b>7</b>
<b>5</b>	<b>PIN DESCRIPTION</b> .....	<b>8</b>
<b>6</b>	<b>FUNCTIONAL BLOCK DESCRIPTIONS</b> .....	<b>11</b>
6.1	MCU INTERFACE SELECTION .....	11
6.1.1	MCU Parallel 6800-series Interface .....	11
6.1.2	MCU Parallel 8080-series Interface .....	12
6.1.3	MCU Serial Interface (4-wire SPI).....	13
6.1.4	MCU Serial Interface (3-wire SPI).....	14
6.1.5	MCU $\dot{P}C$ Interface .....	15
6.2	COMMAND DECODER.....	18
6.3	OSCILLATOR CIRCUIT AND DISPLAY TIME GENERATOR.....	18
6.4	FR SYNCHRONIZATION.....	19
6.5	RESET CIRCUIT .....	19
6.6	SEGMENT DRIVERS/Common Drivers .....	20
6.7	GRAPHIC DISPLAY DATA RAM (GDDRAM).....	23
6.8	SEG/COM DRIVING BLOCK .....	28
6.9	POWER ON AND OFF SEQUENCE .....	29
<b>7</b>	<b>MAXIMUM RATINGS</b> .....	<b>30</b>
<b>8</b>	<b>DC CHARACTERISTICS</b> .....	<b>31</b>
<b>9</b>	<b>AC CHARACTERISTICS</b> .....	<b>32</b>
<b>10</b>	<b>APPLICATION EXAMPLE</b> .....	<b>38</b>

## TABLES

TABLE 3-1: ORDERING INFORMATION .....	6
TABLE 5-1: PIN DESCRIPTION .....	8
TABLE 5-2: BUS INTERFACE SELECTION .....	9
TABLE 6-1: MCU INTERFACE ASSIGNMENT UNDER DIFFERENT BUS INTERFACE MODE .....	11
TABLE 6-2: CONTROL PINS OF 6800 INTERFACE .....	11
TABLE 6-3: CONTROL PINS OF 8080 INTERFACE .....	13
TABLE 6-4: CONTROL PINS OF 4-WIRE SERIAL INTERFACE .....	13
TABLE 6-5: CONTROL PINS OF 3-WIRE SERIAL INTERFACE .....	14
TABLE 6-6: GDDRAM ADDRESS MAP 1 .....	23
TABLE 6-7: GDDRAM ADDRESS MAP 2 .....	24
TABLE 6-8: GDDRAM ADDRESS MAP 3 .....	25
TABLE 6-9: GDDRAM ADDRESS MAP 4 .....	26
TABLE 6-10: GDDRAM ADDRESS MAP 5 .....	27
TABLE 7-1: MAXIMUM RATINGS .....	30
TABLE 8-1: DC CHARACTERISTICS .....	31
TABLE 9-1: AC CHARACTERISTICS .....	32
TABLE 9-2: 6800-SERIES MCU PARALLEL INTERFACE TIMING CHARACTERISTICS .....	33
TABLE 9-3: 8080-SERIES MCU PARALLEL INTERFACE TIMING CHARACTERISTICS .....	34
TABLE 9-4: SERIAL INTERFACE TIMING CHARACTERISTICS (4-WIRE SPI) .....	35
TABLE 9-5: SERIAL INTERFACE TIMING CHARACTERISTICS (3-WIRE SPI) .....	36
TABLE 9-6: I <sup>2</sup> C INTERFACE TIMING CHARACTERISTICS .....	37

Confidential to  
WiseChip Semiconductor Inc.

## FIGURES

FIGURE 4-1 –SSD1320 BLOCK DIAGRAM.....	7
FIGURE 6-1 : DATA READ BACK PROCEDURE - INSERTION OF DUMMY READ .....	12
FIGURE 6-2 : EXAMPLE OF WRITE PROCEDURE IN 8080 PARALLEL INTERFACE MODE.....	12
FIGURE 6-3 : EXAMPLE OF READ PROCEDURE IN 8080 PARALLEL INTERFACE MODE .....	12
FIGURE 6-4 : DISPLAY DATA READ BACK PROCEDURE - INSERTION OF DUMMY READ .....	13
FIGURE 6-5 : WRITE PROCEDURE IN 4-WIRE SERIAL INTERFACE MODE .....	14
FIGURE 6-6 : WRITE PROCEDURE IN 3-WIRE SERIAL INTERFACE MODE .....	14
FIGURE 6-7 : I <sup>2</sup> C-BUS DATA FORMAT .....	16
FIGURE 6-8 : DEFINITION OF THE START AND STOP CONDITION.....	17
FIGURE 6-9 : DEFINITION OF THE ACKNOWLEDGEMENT CONDITION .....	17
FIGURE 6-10 : DEFINITION OF THE DATA TRANSFER CONDITION.....	17
FIGURE 6-11 : OSCILLATOR CIRCUIT AND DISPLAY TIME GENERATOR .....	18
FIGURE 6-12: SEGMENT AND COMMON DRIVER BLOCK DIAGRAM .....	20
FIGURE 6-13 : SEGMENT AND COMMON DRIVER SIGNAL WAVEFORM .....	21
FIGURE 6-14 : GRAY SCALE CONTROL BY PWM IN SEGMENT .....	22
FIGURE 6-15 : I <sub>REF</sub> CURRENT SETTING BY RESISTOR VALUE .....	28
FIGURE 6-16 : POWER ON SEQUENCE .....	29
FIGURE 6-17 : POWER OFF SEQUENCE.....	29
FIGURE 9-1: 6800-SERIES MCU PARALLEL INTERFACE CHARACTERISTICS.....	33
FIGURE 9-2 : 8080-SERIES PARALLEL INTERFACE CHARACTERISTICS .....	34
FIGURE 9-3 : SERIAL INTERFACE CHARACTERISTICS (4-WIRE SPI) .....	35
FIGURE 9-4 : SERIAL INTERFACE CHARACTERISTICS (3-WIRE SPI) .....	36
FIGURE 9-5 : I <sup>2</sup> C INTERFACE TIMING CHARACTERISTICS .....	37
FIGURE 10-1 : APPLICATION EXAMPLE OF SSD1320Z .....	38

Confidential to  
WiseChip Semiconductor Inc.

## 1 GENERAL DESCRIPTION

SSD1320 is a single-chip CMOS OLED/PLED driver with controller for organic/polymer light emitting diode dot-matrix graphic display. It consists of 160 segments and 160 commons. This IC is designed for Common Cathode type OLED/PLED panel.

SSD1320 embeds with contrast control, display RAM and oscillator, which reduce the number of external components and power consumption. It has 160 x 160 x 4 bits Graphic Display Data RAM (GDDRAM), and supports 256-step contrast. Data/Commands are sent from generic MCU through the hardware selectable 6800/8080 series compatible Parallel Interface, I2C interface or Serial Peripheral Interface. SSD1320 is designed to support high brightness panel, with maximum source current reaching 600uA, making it suitable for many compact portable applications which requires sunlight readability, such as wearable electronics etc.

## 2 FEATURES

- Resolution: 160 x 160 dot matrix panel
- Power supply
  - $V_{DD} = 1.65V - 3.5V$  (for IC logic)
  - $V_{CC} = 8.0V - 18.0V$  (for Panel driving)
- Segment maximum source current: 600uA
- Common maximum sink current: 96mA
- Embedded 160 x 160 x 4 bit SRAM display buffer
- Pin selectable MCU Interfaces:
  - 8 bits 6800/8080-series parallel Interface
  - 3/4 wire Serial Peripheral Interface
  - I<sup>2</sup>C Interface
- Screen saving continuous scrolling function in both horizontal and vertical direction
- Screen saving infinite content scrolling function
- Internal or external I<sub>REF</sub> selection
- RAM write synchronization signal
- Programmable Frame Rate and Multiplexing Ratio
- Row Re-mapping and Column Re-mapping
- Power On Reset (POR)
- On-Chip Oscillator
- Power Save Mode
- Chip layout for COG, COF
- Wide range of operating temperature: -40°C to 85°C

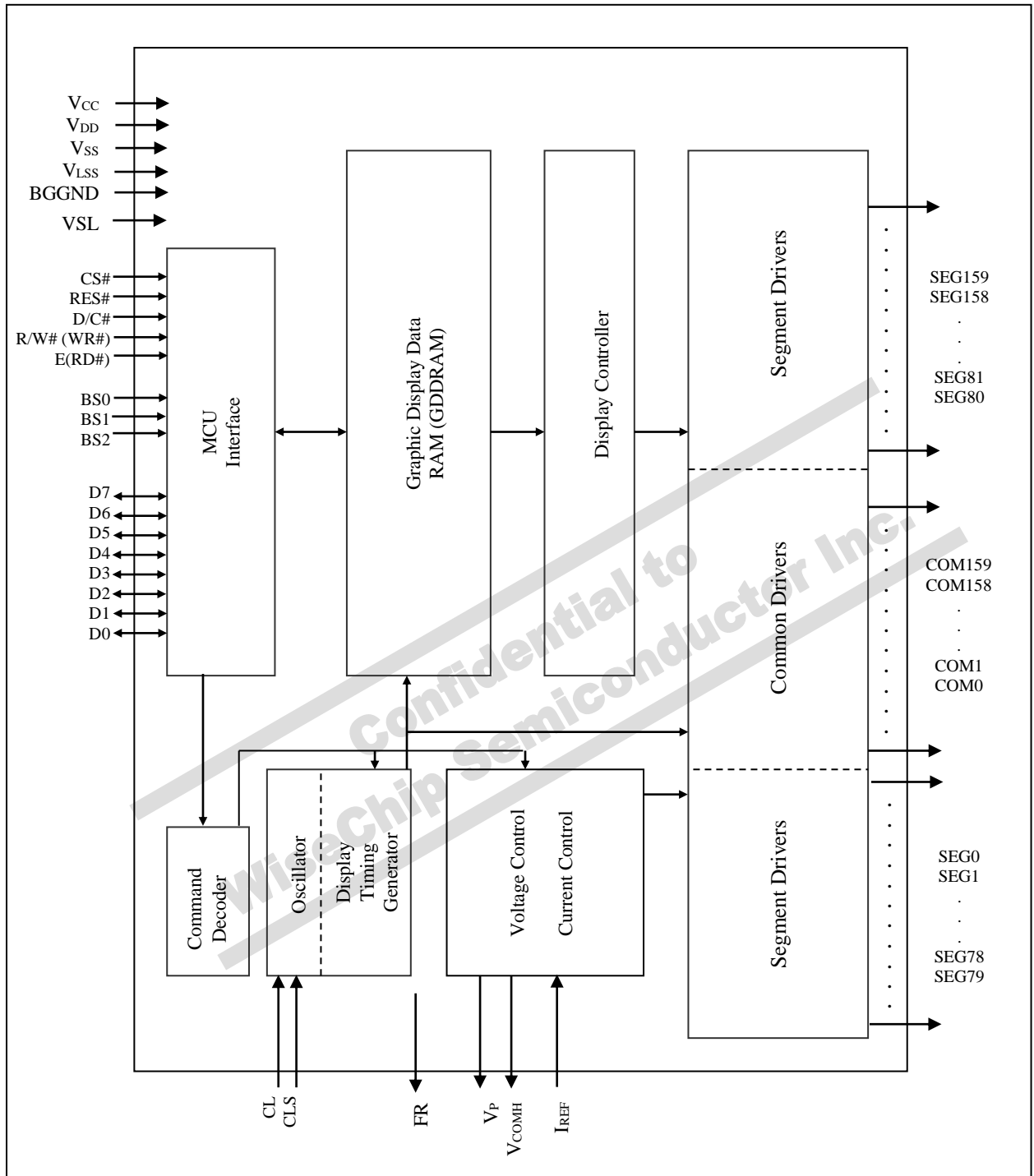
## 3 ORDERING INFORMATION

Table 3-1: Ordering Information

Ordering Part Number	SEG	COM	Package Form	Remark
SSD1320Z	160	160	COG	<ul style="list-style-type: none"><li>○ Min SEG pad pitch : 27um</li><li>○ Min COM pad pitch : 27um</li><li>○ Min I/O pad pitch : 55um</li><li>○ Die thickness: 250um</li><li>○ Bump height: nominal 9um</li></ul>

## 4 BLOCK DIAGRAM

Figure 4-1 –SSD1320 Block Diagram



## 5 PIN DESCRIPTION

Key:

I = Input	NC = Not Connected
O = Output	Pull LOW= connect to Ground
I/O = Bi-directional (input/output)	Pull HIGH= connect to $V_{DD}$
P = Power pin	

**Table 5-1: Pin Description**

Pin Name	Pin Type	Description
$V_{DD}$	P	Power supply pin for core logic operation.
$V_{CC}$	P	Power supply for panel driving voltage. This is also the most positive power voltage supply pin.
BGGND	P	Reserved pin. It must be connected to ground.
$V_{SS}$	P	Ground pin. It must be connected to external ground.
$V_{LSS}$	P	Analog system ground pin. It must be connected to external ground.
VSL	P	This is segment voltage (output low level) reference pin.  When external VSL is not used, this pin should be connected to $V_{LSS}$ externally. When external VSL is used, this pin should be connected with resistor and diode to ground (details depends on application).
$V_{LH}$	P	Logic high (same voltage level as $V_{DD}$ ) for internal connection of input and I/O pins. No need to connect to external power source.
$V_{LL}$	P	Logic low (same voltage level as $V_{SS}$ ) for internal connection of input and I/O pins. No need to connect to external ground.
$V_{COMH}$	P	COM signal deselected voltage level. A capacitor should be connected between this pin and $V_{SS}$ .
$V_P$	P	This pin is the segment pre-charge voltage reference pin.  A capacitor should be connected between this pin and $V_{SS}$ to enhance pre-charge voltage stability if necessary. When external capacitor is not used, this pin should be kept NC. No external power supply is allowed to connect to this pin.
VBREF	O	This is a reserved pin. It should be kept NC.
$I_{REF}$	I	This pin is the segment output current reference pin.  $I_{REF}$ is supplied externally. A resistor should be connected between this pin and $V_{SS}$ to maintain the current around 10uA. Please refer to Figure 6-15 for the details of resistor value. When internal $I_{REF}$ is used, this pin should be kept NC.



Pin Name	Pin Type	Description												
BS[2:0]	I	<p>MCU bus interface selection pins. Select appropriate logic setting as described in the following table. BS2, BS1 and BS0 are pin select.</p> <p style="text-align: center;"><b>Table 5-2 : Bus Interface selection</b></p> <table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>BS[2:0]</th> <th>Interface</th> </tr> </thead> <tbody> <tr> <td>000</td> <td>4 line SPI</td> </tr> <tr> <td>001</td> <td>3 line SPI</td> </tr> <tr> <td>010</td> <td>I<sup>2</sup>C</td> </tr> <tr> <td>110</td> <td>8-bit 8080 parallel</td> </tr> <tr> <td>100</td> <td>8-bit 6800 parallel</td> </tr> </tbody> </table> <p><b>Note</b>  <sup>(1)</sup> 0 is connected to V<sub>SS</sub>  <sup>(2)</sup> 1 is connected to V<sub>DD</sub></p>	BS[2:0]	Interface	000	4 line SPI	001	3 line SPI	010	I <sup>2</sup> C	110	8-bit 8080 parallel	100	8-bit 6800 parallel
BS[2:0]	Interface													
000	4 line SPI													
001	3 line SPI													
010	I <sup>2</sup> C													
110	8-bit 8080 parallel													
100	8-bit 6800 parallel													
CL	I	<p>This is external clock input pin.</p> <p>When internal clock is enabled (i.e. HIGH in CLS pin), this pin is not used and should be connected to V<sub>SS</sub>. When internal clock is disabled (i.e. LOW in CLS pin), this pin is the external clock source input pin.</p>												
CLS	I	<p>This is internal clock enable pin.</p> <p>When it is pulled HIGH (i.e. connect to V<sub>DD</sub>), internal clock is enabled. When it is pulled LOW, the internal clock is disabled; an external clock source must be connected to the CL pin for normal operation.</p>												
CS#	I	<p>This pin is the chip select input connecting to the MCU. The chip is enabled for MCU communication only when CS# is pulled LOW (active LOW).</p>												
RES#	I	<p>This pin is reset signal input.</p> <p>When the pin is pulled LOW, initialization of the chip is executed. Keep this pin pull HIGH during normal operation.</p>												
D/C#	I	<p>This pin is Data/Command control pin connecting to the MCU.</p> <p>When the pin is pulled HIGH, the data at D[7:0] will be interpreted as data. When the pin is pulled LOW, the data at D[7:0] will be transferred to a command register.</p> <p>In I<sup>2</sup>C mode, this pin acts as SA0 for slave address selection. When 3-wire serial interface is selected, this pin must be connected to V<sub>SS</sub>.</p> <p>For detail relationship to MCU interface signals, refer to Timing Characteristics Diagrams at Figure 9-3</p>												
R/W# (WR#)	I	<p>This pin is read / write control input pin connecting to the MCU interface.</p> <p>When 6800 interface mode is selected, this pin will be used as Read/Write (R/W#) selection input. Read mode will be carried out when this pin is pulled HIGH and write mode when LOW.</p> <p>When 8080 interface mode is selected, this pin will be the Write (WR#) input. Data write operation is initiated when this pin is pulled LOW and the chip is selected.</p> <p>When serial or I<sup>2</sup>C interface is selected, this pin must be connected to V<sub>SS</sub>.</p>												

Pin Name	Pin Type	Description
E (RD#)	I	<p>This pin is MCU interface input.</p> <p>When 6800 interface mode is selected, this pin will be used as the Enable (E) signal. Read/write operation is initiated when this pin is pulled HIGH and the chip is selected.</p> <p>When 8080 interface mode is selected, this pin receives the Read (RD#) signal. Read operation is initiated when this pin is pulled LOW and the chip is selected.</p> <p>When serial or I<sup>2</sup>C interface is selected, this pin must be connected to V<sub>SS</sub>.</p>
D[7:0]	I/O	<p>These pins are bi-directional data bus connecting to the MCU data bus. Unused pins are recommended to tie LOW.</p> <p>When serial interface mode is selected, D2, D1 should be tied together as the serial data input: SDIN, and D0 will be the serial clock input: SCLK.</p> <p>When I<sup>2</sup>C mode is selected, D2, D1 should be tied together and serve as SDA<sub>out</sub>, SDA<sub>in</sub> in application and D0 is the serial clock input, SCL.</p>
FR	O	<p>This pin outputs RAM write synchronization signal. Proper timing between MCU data writing and frame display timing can be achieved to prevent tearing effect. It should be kept NC if it is not used.</p>
T0	I/O	This is a reserved pin. It should be kept NC.
T1	I/O	This is a reserved pin. It should be kept NC.
SEG0 ~ SEG159	O	These pins provide the OLED segment driving signals. These pins are V <sub>SS</sub> state when display is OFF.
COM0 ~ COM159	O	These pins provide the Common switch signals to the OLED panel. These pins are in high impedance state when display is OFF.
TR[15:0]	-	Reserved pin and is recommended to keep it float.
NC	-	This is dummy pin. It should be kept NC.

## 6 FUNCTIONAL BLOCK DESCRIPTIONS

### 6.1 MCU Interface selection

SSD1320 MCU interface consist of 8 data pins and 5 control pins. The pin assignment at different interface mode is summarized in Table 6-1. Different MCU mode can be set by hardware selection on BS[2:0] pins (please refer to Table 5-2 for BS[2:0] setting).

**Table 6-1 : MCU interface assignment under different bus interface mode**

Pin Name Bus Interface	Data/Command Interface								Control Signal				
	D7	D6	D5	D4	D3	D2	D1	D0	E	R/W#	CS#	D/C#	RES#
8-bit 8080	D[7:0]								RD#	WR#	CS#	D/C#	RES#
8-bit 6800	D[7:0]								E	R/W#	CS#	D/C#	RES#
3-wire SPI	Tie LOW				SDIN		SCLK	Tie LOW		CS#	Tie LOW	RES#	
4-wire SPI	Tie LOW				SDIN		SCLK	Tie LOW		CS#	D/C#	RES#	
I <sup>2</sup> C	Tie LOW				SDA <sub>OUT</sub>	SDA <sub>IN</sub>	SCL	Tie LOW			SA0	RES#	

When serial interface mode is selected, D0 will be the serial clock input: SCLK; D1 and D2 should be tied together as the serial data input: SDIN.

#### 6.1.1 MCU Parallel 6800-series Interface

The parallel interface consists of 8 bi-directional data pins (D[7:0]), R/W#, D/C#, E and CS#.

A LOW in R/W# indicates WRITE operation and HIGH in R/W# indicates READ operation.

A LOW in D/C# indicates COMMAND read/write and HIGH in D/C# indicates DATA read/write.

The E input serves as data latch signal while CS# is LOW. Data is latched at the falling edge of E signal.

**Table 6-2 : Control pins of 6800 interface**

Function	E	R/W#	CS#	D/C#
Write command	↓	L	L	L
Read status	↓	H	L	L
Write data	↓	L	L	H
Read data	↓	H	L	H

#### Note

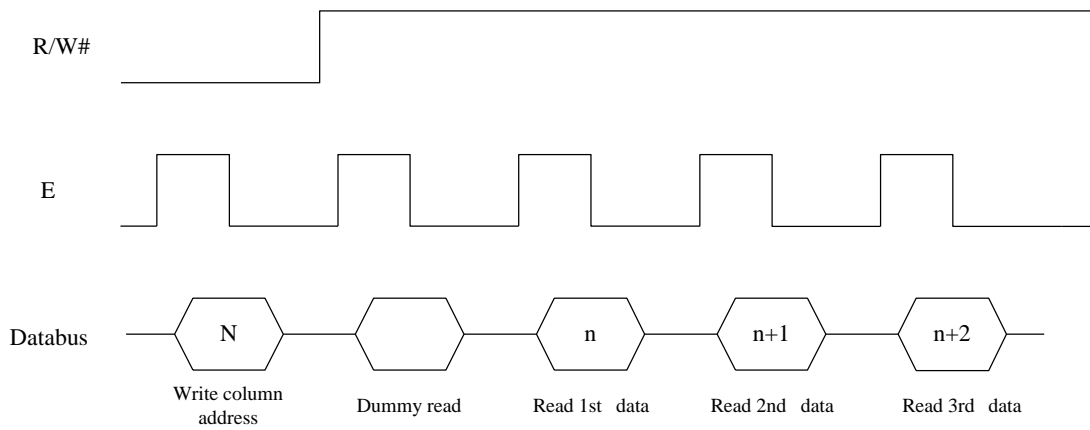
<sup>(1)</sup> ↓ stands for falling edge of signal

H stands for HIGH in signal

L stands for LOW in signal

In order to match the operating frequency of display RAM with that of the microprocessor, some pipeline processing is internally performed which requires the insertion of a dummy read before the first actual display data read. This is shown in Figure 6-1.

**Figure 6-1 : Data read back procedure - insertion of dummy read**



### 6.1.2 MCU Parallel 8080-series Interface

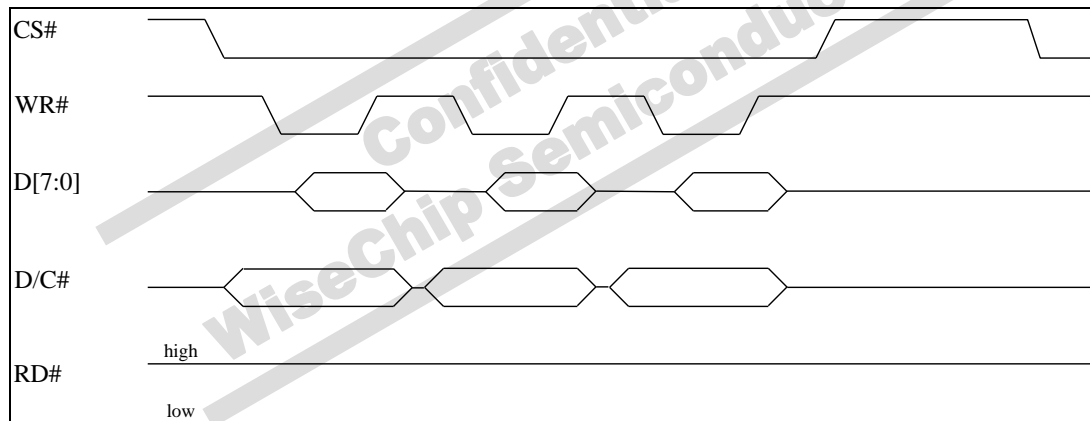
The parallel interface consists of 8 bi-directional data pins (D[7:0]), RD#, WR#, D/C# and CS#.

A LOW in D/C# indicates COMMAND read/write and HIGH in D/C# indicates DATA read/write.

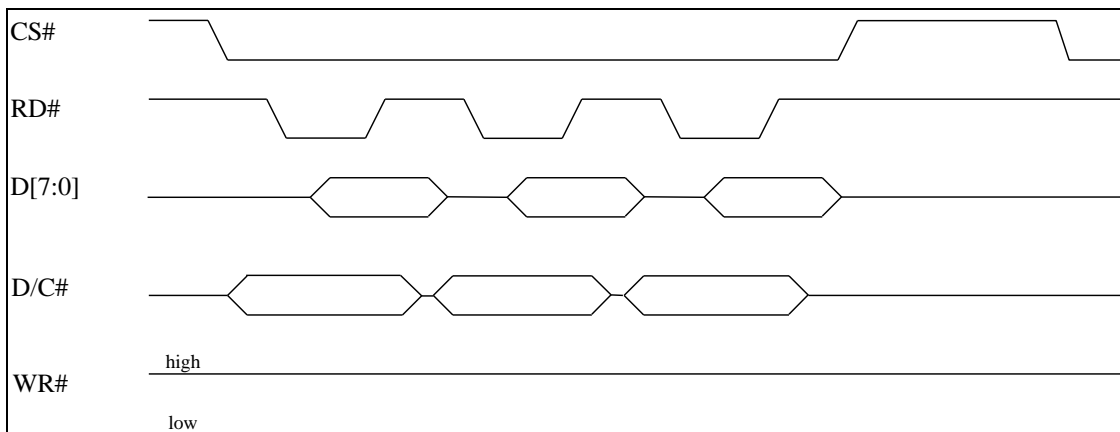
A rising edge of RD# input serves as a data READ latch signal while CS# is kept LOW.

A rising edge of WR# input serves as a data/command WRITE latch signal while CS# is kept LOW.

**Figure 6-2 : Example of Write procedure in 8080 parallel interface mode**



**Figure 6-3 : Example of Read procedure in 8080 parallel interface mode**



**Table 6-3 : Control pins of 8080 interface**

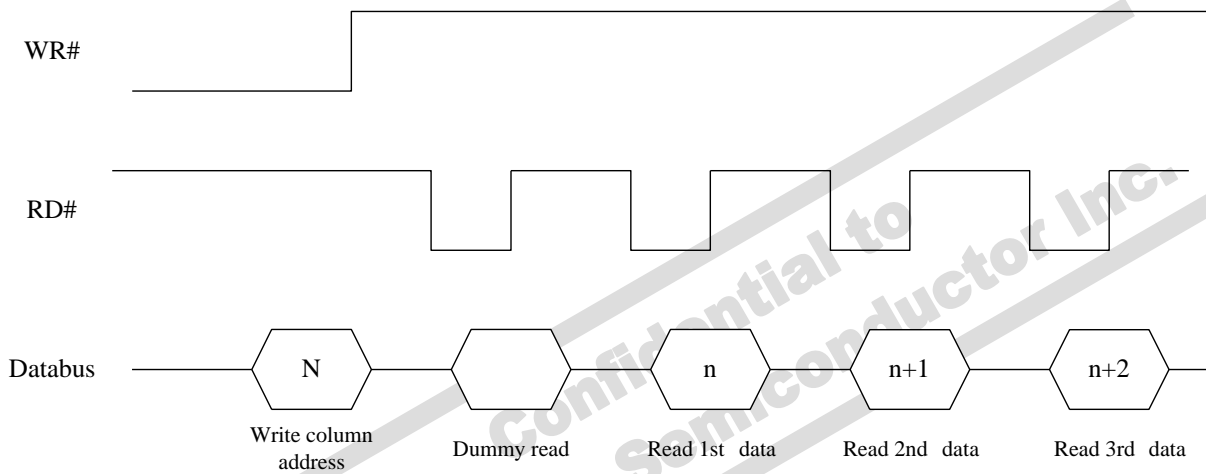
Function	RD#	WR#	CS#	D/C#
Write command	H	↑	L	L
Read status	↑	H	L	L
Write data	H	↑	L	H
Read data	↑	H	L	H

**Note**

- (1) ↑ stands for rising edge of signal
- (2) H stands for HIGH in signal
- (3) L stands for LOW in signal

In order to match the operating frequency of display RAM with that of the microprocessor, some pipeline processing is internally performed which requires the insertion of a dummy read before the first actual display data read. This is shown in Figure 6-4.

**Figure 6-4 : Display data read back procedure - insertion of dummy read**



**6.1.3 MCU Serial Interface (4-wire SPI)**

The 4-wire serial interface consists of serial clock: SCLK, serial data: SDIN, D/C#, CS#. In 4-wire SPI mode, D0 acts as SCLK, D1 and D2 are tied together to act as SDIN. For the unused data pins from D3 to D7, E(RD#) and R/W#(WR#) can be connected to an external ground.

**Table 6-4 : Control pins of 4-wire Serial interface**

Function	E	R/W#	CS#	D/C#	D0
Write command	Tie LOW	Tie LOW	L	L	↑
Write data	Tie LOW	Tie LOW	L	H	↑

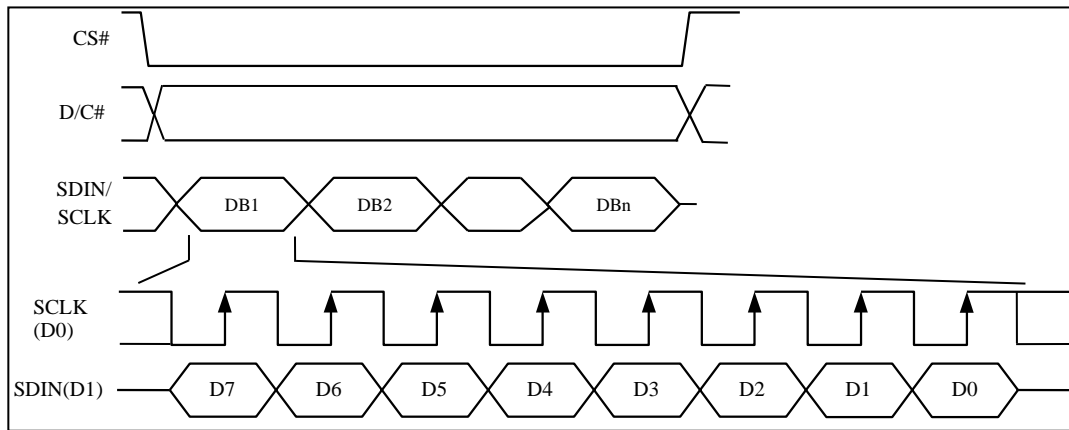
**Note**

- (1) H stands for HIGH in signal
- (2) L stands for LOW in signal
- (3) ↑ stands for rising edge of signal

SDIN is shifted into an 8-bit shift register on every rising edge of SCLK in the order of D7, D6, ..., D0. D/C# is sampled on every eighth clock and D/C# should be kept stable throughout eight clock period. The data byte in the shift register is written to the Graphic Display Data RAM (GDDRAM) or command register in the same clock.

Under serial mode, only write operations are allowed.

**Figure 6-5 : Write procedure in 4-wire Serial interface mode**



### 6.1.4 MCU Serial Interface (3-wire SPI)

The 3-wire serial interface consists of serial clock SCLK, serial data SDIN and CS#.

In 3-wire SPI mode, D0 acts as SCLK, D1 and D2 are tied together to act as SDIN. For the unused data pins from D3 to D7, R/W# (WR#), E(RD#) and D/C# can be connected to an external ground.

The operation is similar to 4-wire serial interface while D/C# pin is not used. There are altogether 9-bits will be shifted into the shift register on every ninth clock in sequence: D/C# bit, D7 to D0 bit. The D/C# bit (first bit of the sequential data) will determine the following data byte in the shift register is written to the Display Data RAM (D/C# bit = 1) or the command register (D/C# bit = 0).

Under serial mode, only write operations are allowed.

**Table 6-5 : Control pins of 3-wire Serial interface**

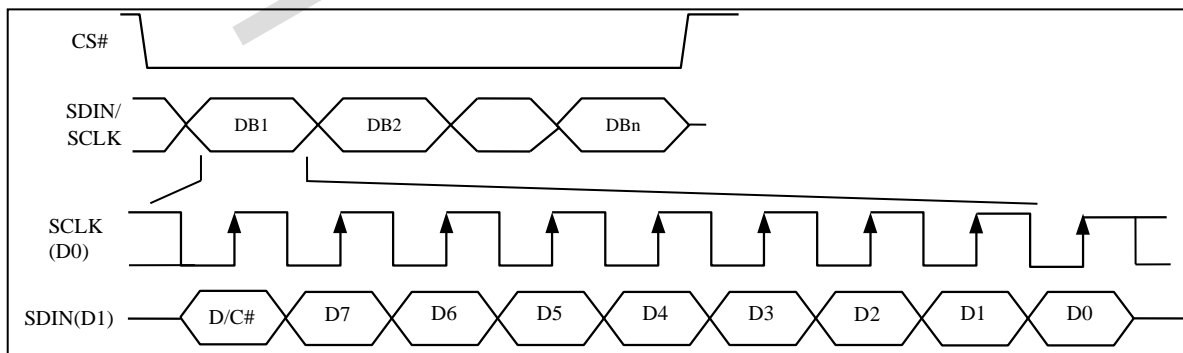
Function	E(RD#)	R/W#(WR#)	CS#	D/C#	D0
Write command	Tie LOW	Tie LOW	L	Tie LOW	↑
Write data	Tie LOW	Tie LOW	L	Tie LOW	↑

**Note**

(1) L stands for LOW in signal

(2) ↑ stands for rising edge of signal

**Figure 6-6 : Write procedure in 3-wire Serial interface mode**



### 6.1.5 MCU I<sup>2</sup>C Interface

The I<sup>2</sup>C communication interface consists of slave address bit SA0, I<sup>2</sup>C-bus data signal SDA (SDA<sub>OUT</sub>/D<sub>2</sub> for output and SDA<sub>IN</sub>/D<sub>1</sub> for input) and I<sup>2</sup>C-bus clock signal SCL (D<sub>0</sub>). Both the data and clock signals must be connected to pull-up resistors. RES# is used for the initialization of device.

a) Slave address bit (SA0)

SSD1320 has to recognize the slave address before transmitting or receiving any information by the I<sup>2</sup>C-bus. The device will respond to the slave address following by the slave address bit (“SA0” bit) and the read/write select bit (“R/W#” bit) with the following byte format,

```
b7 b6 b5 b4 b3 b2 b1 b0
0 1 1 1 1 0 SA0 R/W#
```

“SA0” bit provides an extension bit for the slave address. Either “0111100” or “0111101”, can be selected as the slave address of SSD1320. D/C# pin acts as SA0 for slave address selection.

“R/W#” bit is used to determine the operation mode of the I<sup>2</sup>C-bus interface. R/W#=1, it is in read mode. R/W#=0, it is in write mode.

b) I<sup>2</sup>C-bus data signal (SDA)

SDA acts as a communication channel between the transmitter and the receiver. The data and the acknowledgement are sent through the SDA.

It should be noticed that the ITO track resistance and the pulled-up resistance at “SDA” pin becomes a voltage potential divider. As a result, the acknowledgement would not be possible to attain a valid logic 0 level in “SDA”.

“SDA<sub>IN</sub>” and “SDA<sub>OUT</sub>” are tied together and serve as SDA. The “SDA<sub>IN</sub>” pin must be connected to act as SDA. The “SDA<sub>OUT</sub>” pin may be disconnected. When “SDA<sub>OUT</sub>” pin is disconnected, the acknowledgement signal will be ignored in the I<sup>2</sup>C-bus.

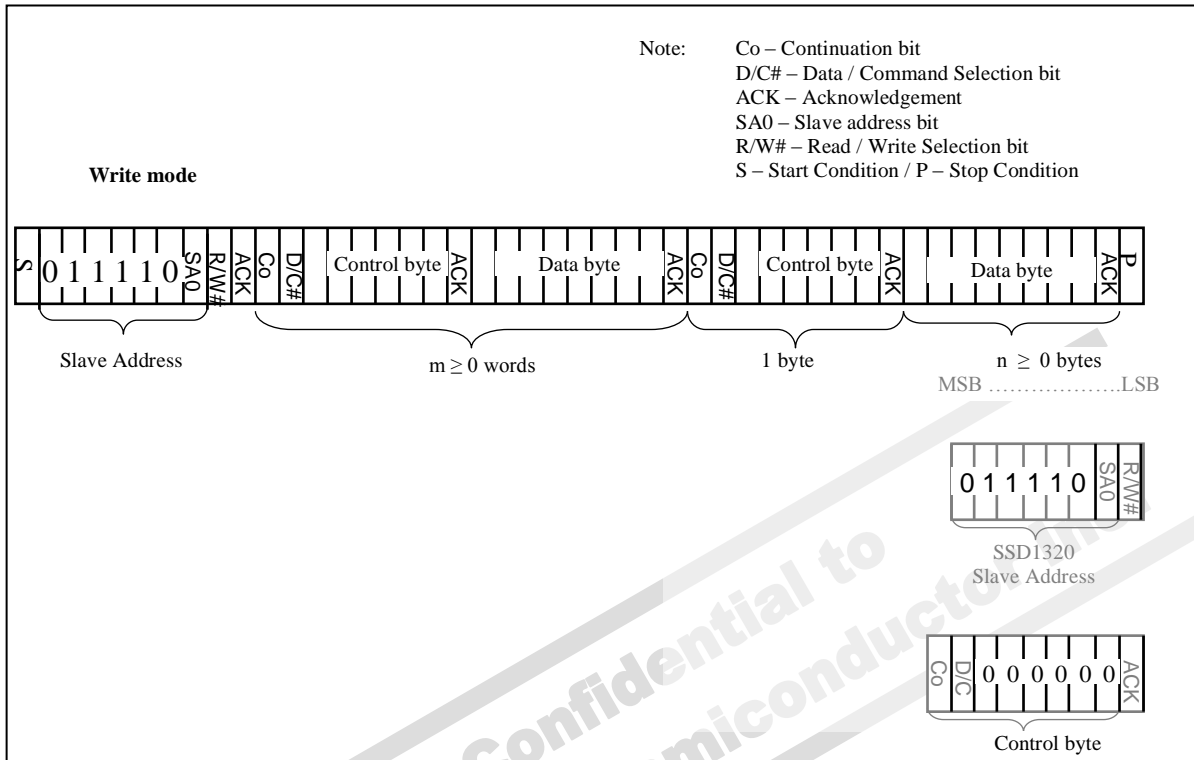
c) I<sup>2</sup>C-bus clock signal (SCL)

The transmission of information in the I<sup>2</sup>C-bus is following a clock signal, SCL. Each transmission of data bit is taken place during a single clock period of SCL.

### 6.1.5.1 I<sup>2</sup>C-bus Write data

The I<sup>2</sup>C-bus interface gives access to write data and command into the device. Please refer to Figure 6-7 for the write mode of I<sup>2</sup>C-bus in chronological order.

Figure 6-7 : I<sup>2</sup>C-bus data format

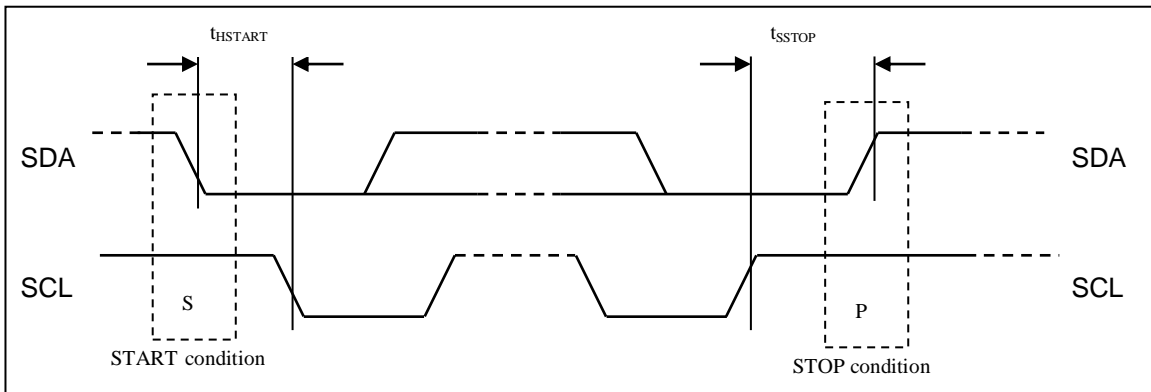


### 6.1.5.2 Write mode for I<sup>2</sup>C

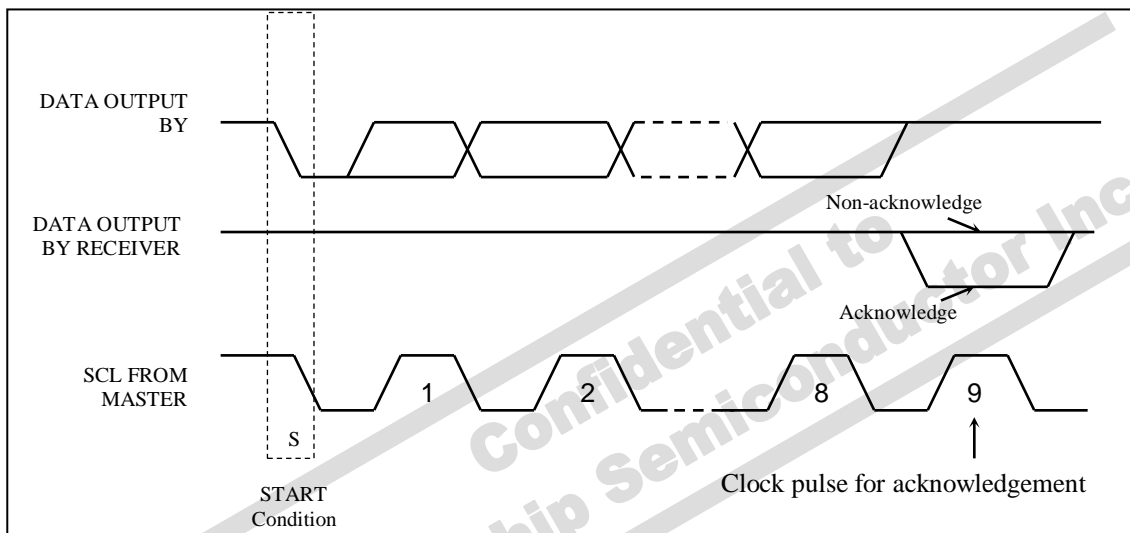
- 1) The master device initiates the data communication by a start condition. The definition of the start condition is shown in Figure 6-8. The start condition is established by pulling the SDA from HIGH to LOW while the SCL stays HIGH.
- 2) The slave address is following the start condition for recognition use. For the SSD1320, the slave address is either “b0111100” or “b0111101” by changing the SA0 to LOW or HIGH (D/C pin acts as SA0).
- 3) The write mode is established by setting the R/W# bit to logic “0”.
- 4) An acknowledgement signal will be generated after receiving one byte of data, including the slave address and the R/W# bit. Please refer to the Figure 6-9 : Definition of the acknowledgement condition for the graphical representation of the acknowledge signal. The acknowledge bit is defined as the SDA line is pulled down during the HIGH period of the acknowledgement related clock pulse.
- 5) After the transmission of the slave address, either the control byte or the data byte may be sent across the SDA. A control byte mainly consists of Co and D/C# bits following by six “0” ‘s.
  - a. If the Co bit is set as logic “0”, the transmission of the following information will contain data bytes only.
  - b. The D/C# bit determines the next data byte is acted as a command or a data. If the D/C# bit is set to logic “0”, it defines the following data byte as a command. If the D/C# bit is set to logic “1”, it defines the following data byte as a data which will be stored at the GDDRAM. The GDDRAM column address pointer will be increased by one automatically after each data write.
- 6) Acknowledge bit will be generated after receiving each control byte or data byte.
- 7) The write mode will be finished when a stop condition is applied. The stop condition is also defined in Figure 6-8. The stop condition is established by pulling the “SDA in” from LOW to HIGH while the “SCL” stays HIGH.



**Figure 6-8 : Definition of the Start and Stop Condition**



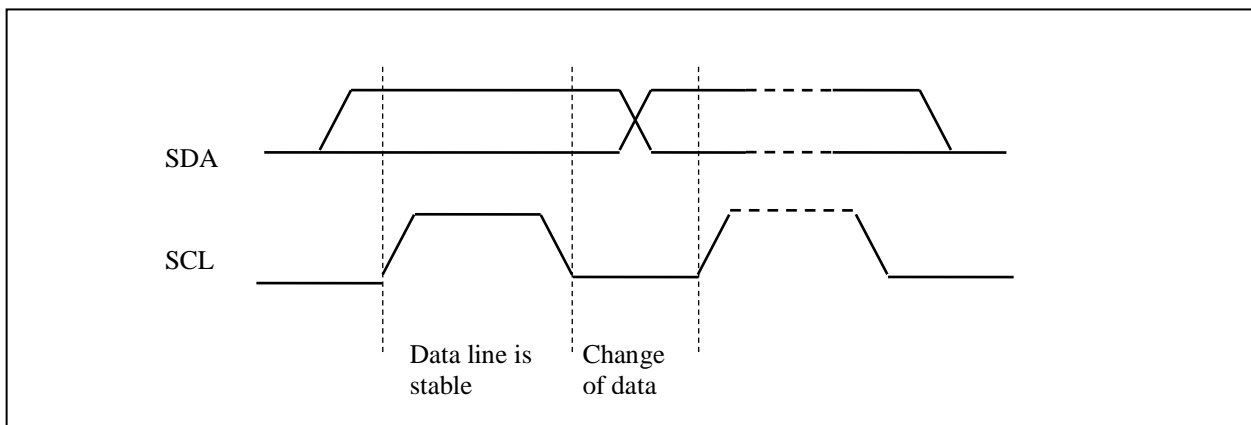
**Figure 6-9 : Definition of the acknowledgement condition**



Please be noted that the transmission of the data bit has some limitations.

1. The data bit, which is transmitted during each SCL pulse, must keep at a stable state within the "HIGH" period of the clock pulse. Please refer to the Figure 6-10 for graphical representations. Except in start or stop conditions, the data line can be switched only when the SCL is LOW.
2. Both the data line (SDA) and the clock line (SCL) should be pulled up by external resistors.

**Figure 6-10 : Definition of the data transfer condition**



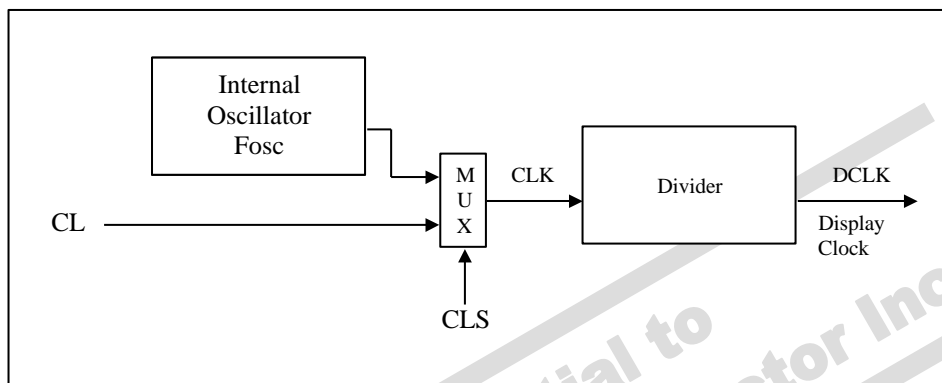
## 6.2 Command Decoder

This module determines whether the input data is interpreted as data or command. Data is interpreted based upon the input of the D/C# pin.

If D/C# pin is HIGH, D[7:0] is interpreted as display data written to Graphic Display Data RAM (GDDRAM). If it is LOW, the input at D[7:0] is interpreted as a command. Then data input will be decoded and written to the corresponding command register.

## 6.3 Oscillator Circuit and Display Time Generator

Figure 6-11 : Oscillator Circuit and Display Time Generator



This module is an on-chip LOW power RC oscillator circuitry. The operation clock (CLK) can be generated either from internal oscillator or external source CL pin. This selection is done by CLS pin. If CLS pin is pulled HIGH, internal oscillator is chosen and CL should be connected to V<sub>SS</sub>. Pulling CLS pin LOW disables internal oscillator and external clock must be connected to CL pins for proper operation. When the internal oscillator is selected, its output frequency F<sub>osc</sub> can be changed by command D5h A[7:4].

The display clock (DCLK) for the Display Timing Generator is derived from CLK. The division factor “D” can be programmed from 1 to 256 by command D5h

$$DCLK = F_{osc} / D$$

The frame frequency of display is determined by the following formula.

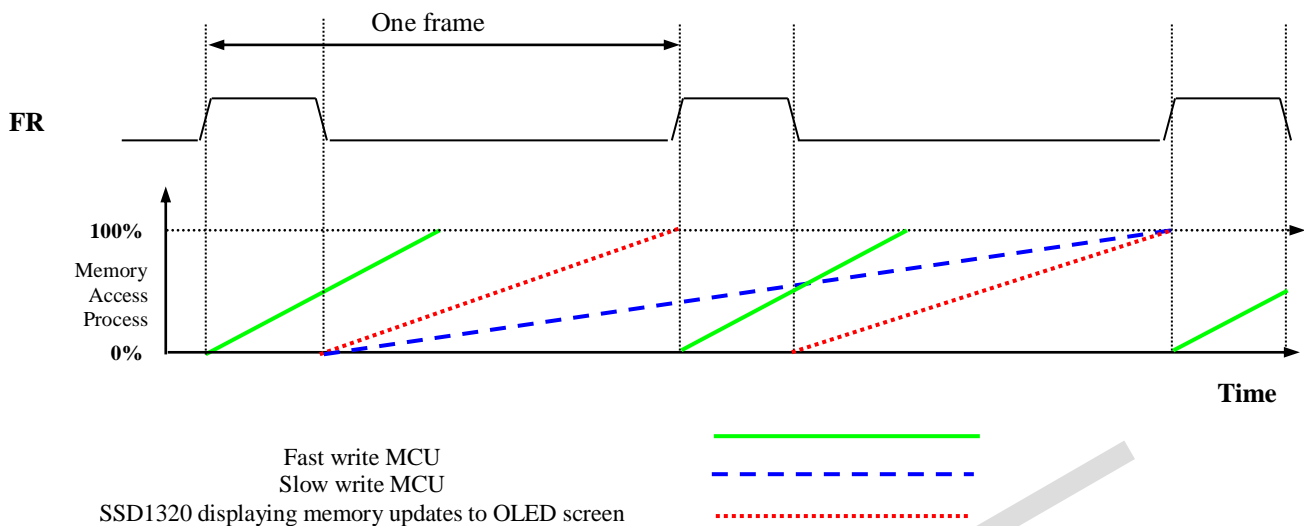
$$F_{FRM} = \frac{F_{osc}}{D \times K \times \text{No. of Mux}}$$

where

- D stands for clock divide ratio. It is set by command D5h A[3:0]. The divide ratio has the range from 1 to 256.
- K is the number of display clocks per row. The value is derived by  
 $K = \text{Phase 1 period} + \text{Phase 2 period} + K_0$   
 $= 7 + 2 + 66 = 75$  at power on reset (that is K<sub>0</sub> is a constant that equals to 66)  
 Please refer to Section 6.6 for the details of the “Phase”.
- Number of multiplex ratio is set by command A8h. The power on reset value is 159 (i.e. 160MUX).
- F<sub>osc</sub> is the oscillator frequency. It can be changed by command D5h A[7:4]. The higher the register setting results in higher frequency.

## 6.4 FR synchronization

FR synchronization signal can be used to prevent tearing effect.



The starting time to write a new image to OLED driver is depended on the MCU writing speed. If MCU can finish writing a frame image within one frame period, it is classified as fast write MCU. For MCU needs longer writing time to complete (more than one frame but within two frames), it is a slow write one.

**For fast write MCU:** MCU should start to write new frame of ram data just after rising edge of FR pulse and should be finished well before the rising edge of the next FR pulse.

**For slow write MCU:** MCU should start to write new frame ram data after the falling edge of the 1<sup>st</sup> FR pulse and must be finished before the rising edge of the 3<sup>rd</sup> FR pulse.

## 6.5 Reset Circuit

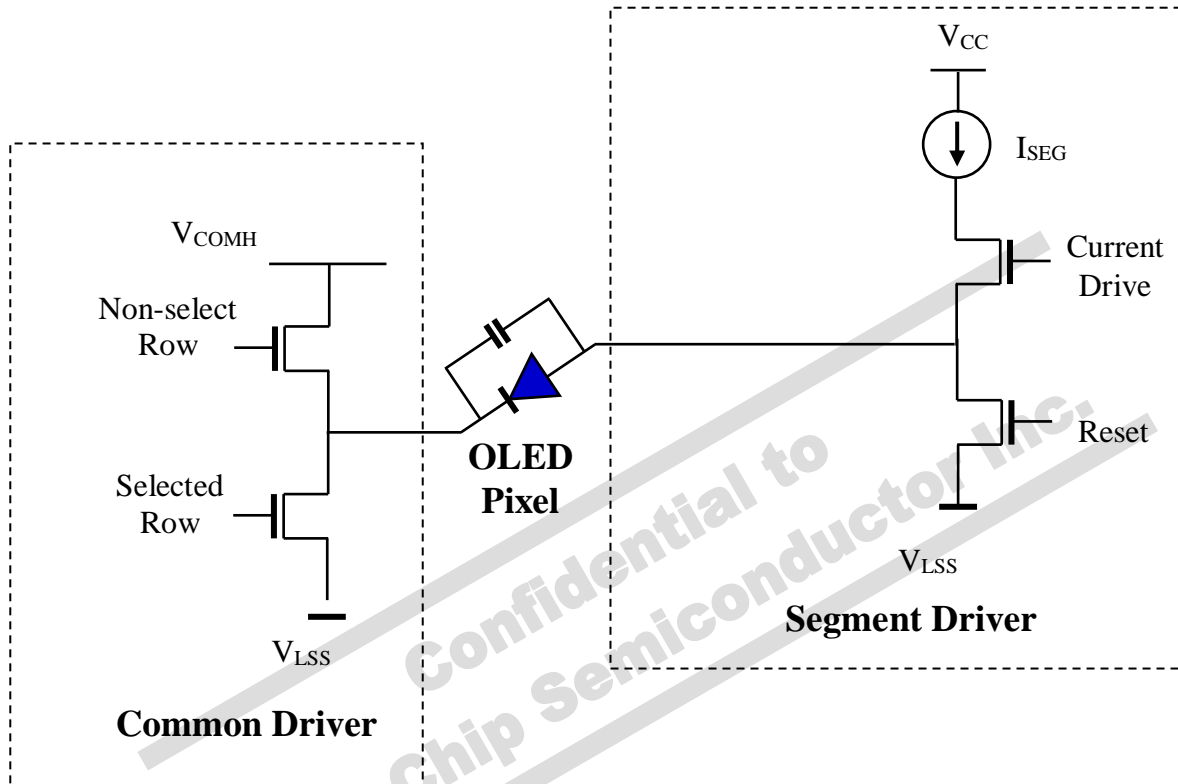
When RES# input is LOW, the chip is initialized with the following status:

1. Display is OFF
2. 160 x 160 Display Mode
3. Normal segment and display data column address and row address mapping (SEG0 mapped to address 00h and COM0 mapped to address 00h)
4. Shift register data clear in serial interface
5. Display start line is set at display RAM address 0
6. Column address counter is set at 0
7. Normal scan direction of the COM outputs
8. Contrast control register is set at 7Fh
9. Normal display mode (Equivalent to A4h command)

## 6.6 Segment Drivers/Common Drivers

Segment drivers have 160 current sources to drive OLED panel. The driving current can be adjusted up to 600uA with 8 bits, 256 steps by contrast setting command (81h). Common drivers generate voltage scanning pulses. The block diagrams and waveforms of the segment and common driver are shown as follow.

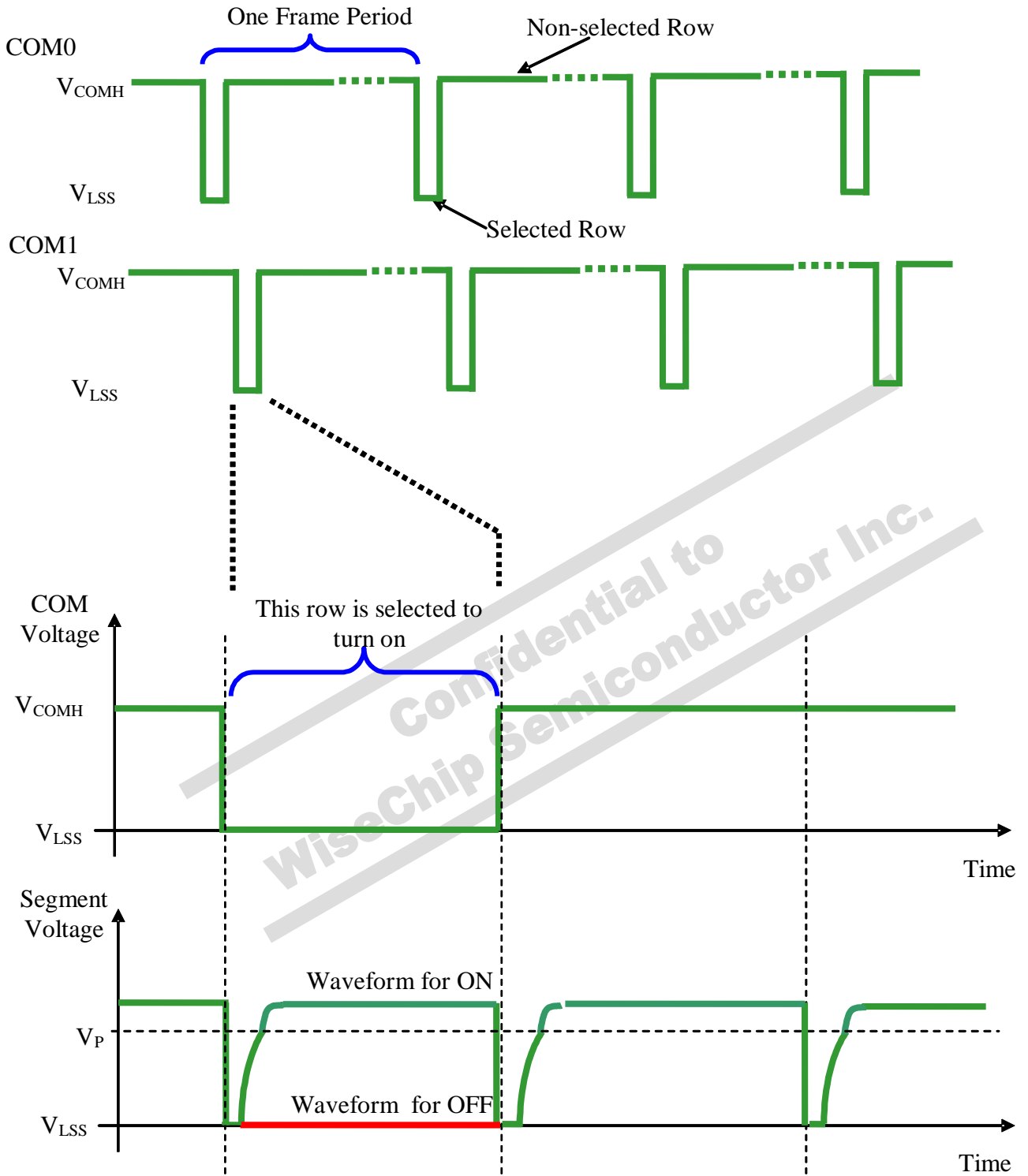
**Figure 6-12: Segment and Common Driver Block Diagram**



The commons are scanned sequentially, row by row. If a row is not selected, all the pixels on the row are in reverse bias by driving those commons to voltage  $V_{COMH}$  as shown in Figure 6-13.

In the scanned row, the pixels on the row will be turned ON or OFF by sending the corresponding data signal to the segment pins.

Figure 6-13 : Segment and Common Driver Signal Waveform



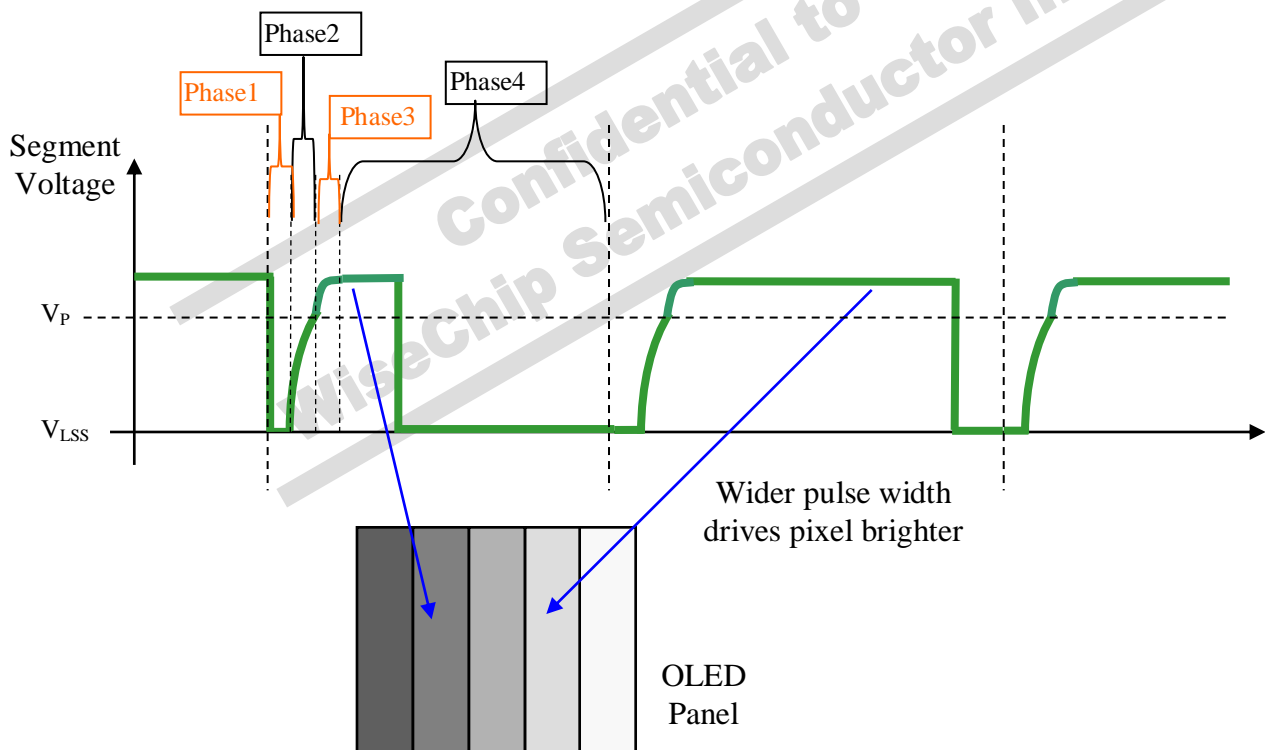
There are four phases to driving an OLED a pixel. In phase 1, the pixel is reset by the segment driver to  $V_{LSS}$  in order to discharge the previous data charge stored in the parasitic capacitance along the segment electrode. The period of phase 1 can be programmed by command D9h A[3:0]. An OLED panel with larger capacitance requires a longer period for discharging.

In phase 2, first pre-charge is performed. The pixel is driven to attain the corresponding voltage level  $V_P$  from  $V_{LSS}$ . The amplitude of  $V_P$  can be programmed by the command BCh. The period of phase 2 can be programmed by command D9h A[7:4]. If the capacitance value of the pixel of OLED panel is larger, a longer period is required to charge up the capacitor to reach the desired voltage.

In phase 3, the OLED pixel is driven to the targeted driving voltage through second pre-charge. The second pre-charge can control the speed of the charging process. The period of phase 3 can be programmed by command DCh.

Last phase (phase 4) is current drive stage. The current source in the segment driver delivers constant current to the pixel. The driver IC employs PWM (Pulse Width Modulation) method to control the gray scale of each pixel individually. The gray scale can be programmed into different Gamma settings by command BEh/BFh. The bigger gamma setting (the wider pulse widths) in the current drive stage results in brighter pixels and vice versa. This is shown in the following figure.

**Figure 6-14 : Gray Scale Control by PWM in Segment**



After finishing phase 4, the driver IC will go back to phase 1 to display the next row image data. This four-step cycle is run continuously to refresh image display on OLED panel.

The length of phase 4 is defined by command BEh/BFh. In the table, the gray scale is defined in incremental way, with reference to the length of previous table entry.

## 6.7 Graphic Display Data RAM (GDDRAM)

The GDDRAM is a bit mapped static RAM holding the bit pattern to be displayed. The size of the RAM is 160x160x4 bits. For mechanical flexibility, re-mapping on both Segment and Common outputs can be selected by software. The GDDRAM address maps in Table 6-6 to Table 6-10 show some examples to re-map the GDDRAM. In the following tables, the lower nibble and higher nibble of D0, D1, D2 ... D12797, D12798, D12799 represent the 160x160 data bytes in the GDDRAM.

These are the commands for Re-map setting:

Description	Type	Register
Disable/Enable Column Address Re-map	Single Byte	A0h/A1h
Horizontal/Vertical Address Increment	Double Byte	20h 00h/01h
Disable/Enable COM Re-map	Single Byte	C0h/C8h
Disable/Enable Portrait Mode	Double Byte	25h 00h/01h

Table 6-6 shows the GDDRAM map under the following condition:

- Command Setting:
  - Disable Column Address Re-map    A0h
  - Horizontal Address Increment    20h 00h
  - Disable COM Re-map    C0h
  - Disable Portrait Mode    25h 00h
- Display Start Line=00h
- Data byte sequence: D0, D1, D2 ... D12799

Table 6-6 : GDDRAM address map 1

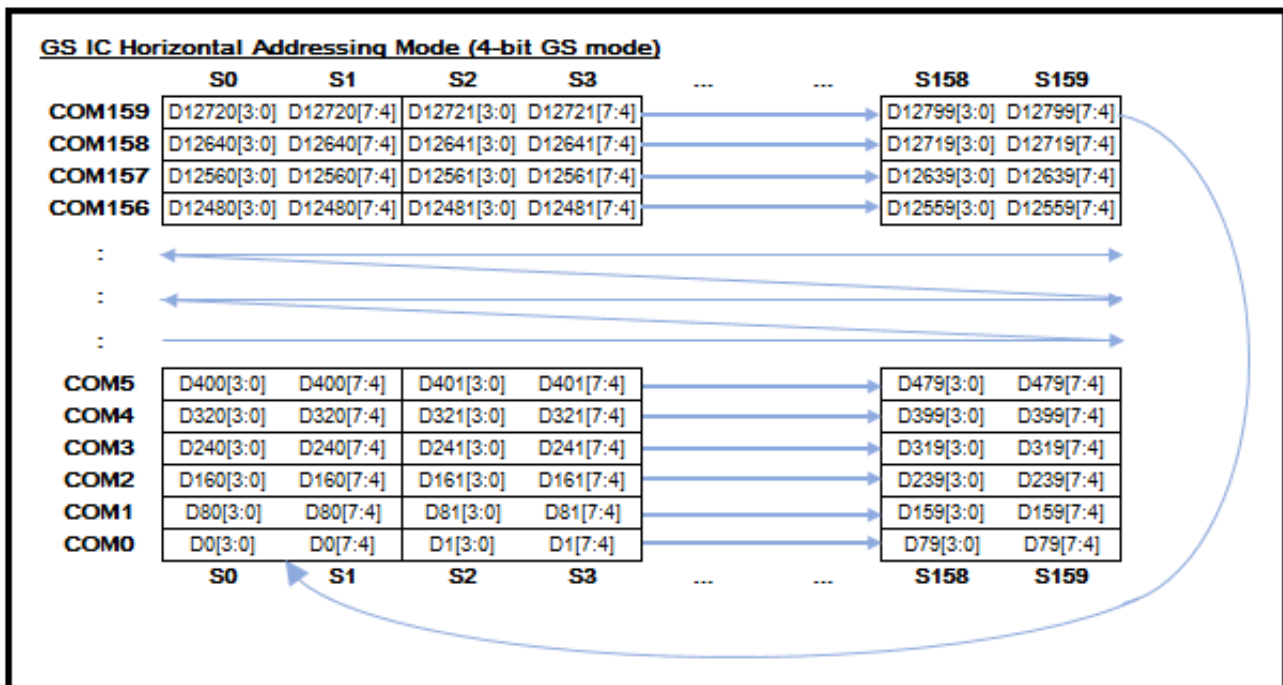


Table 6-7 shows the GDDRAM map under the following condition:

- Command Setting:
  - Disable Column Address Re-map A0h
  - Vertical Address Increment 20h 01h
  - Disable COM Re-map C0h
  - Disable Portrait Mode 25h 00h
- Display Start Line=00h
- Data byte sequence: D0, D1, D2 ... D12799

**Table 6-7 : GDDRAM address map 2**

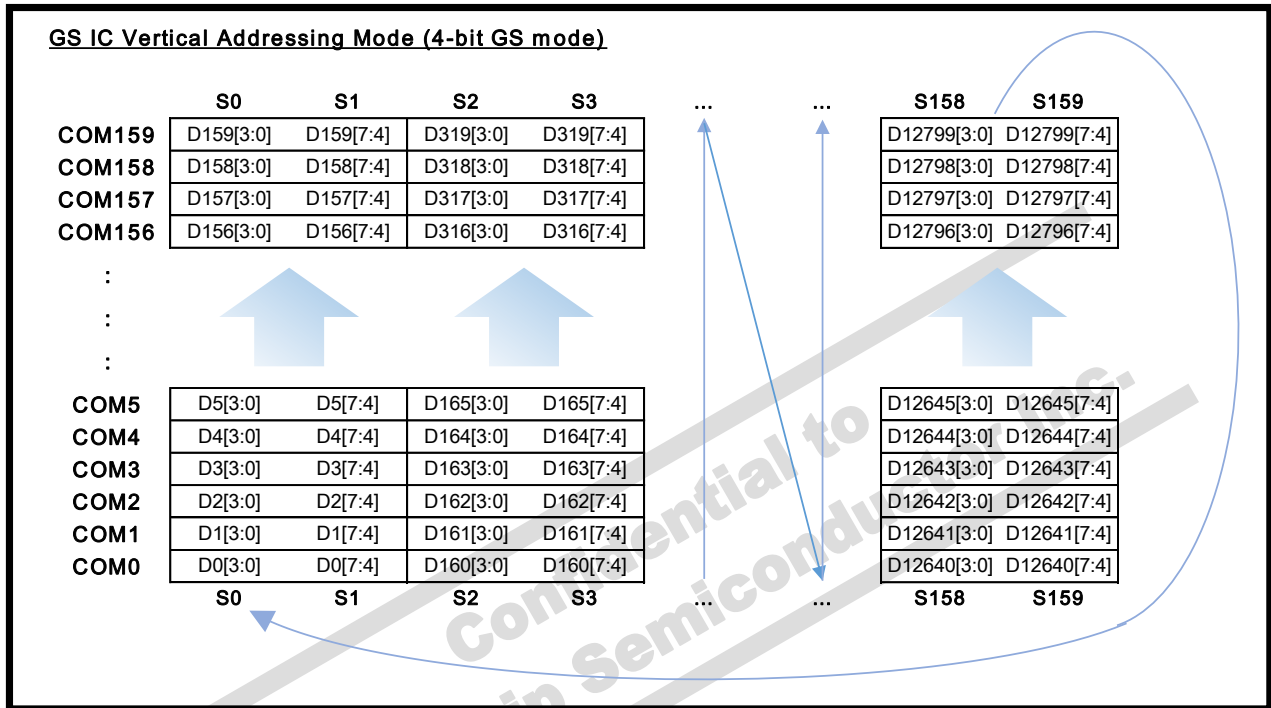




Table 6-8 shows the GDDRAM map under the following condition:

- Command Setting:
 

Enable Column Address Re-map	A1h
Horizontal Address Increment	20h 00h
Disable COM Re-map	C0h
Disable Portrait Mode	25h 00h
- Display Start Line=00h
- Data byte sequence: D0, D1, D2 ... D12799

**Table 6-8 : GDDRAM address map 3**

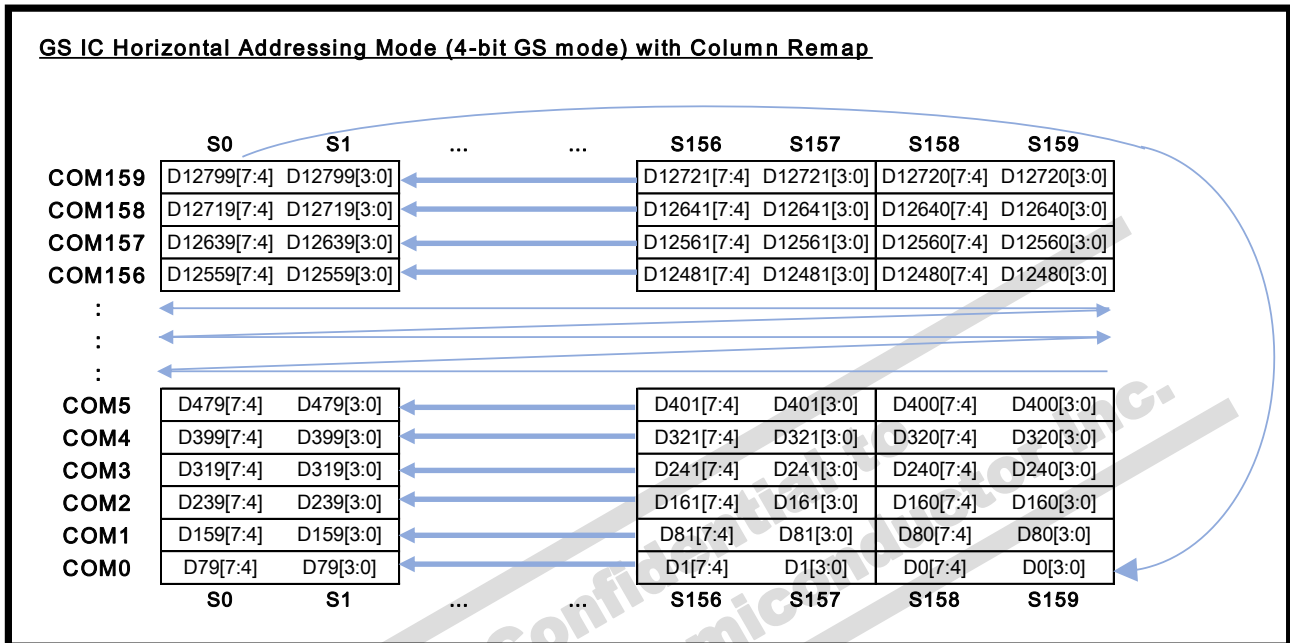


Table 6-9 shows the GDDRAM map under the following condition:

- Command Setting:
 

Disable Column Address Re-map	A0h
Horizontal Address Increment	20h 00h
Enable COM Re-map	C8h
Disable Portrait Mode	25h 00h
- Display Start Line=00h
- Data byte sequence: D0, D1, D2 ... D12799

**Table 6-9 : GDDRAM address map 4**

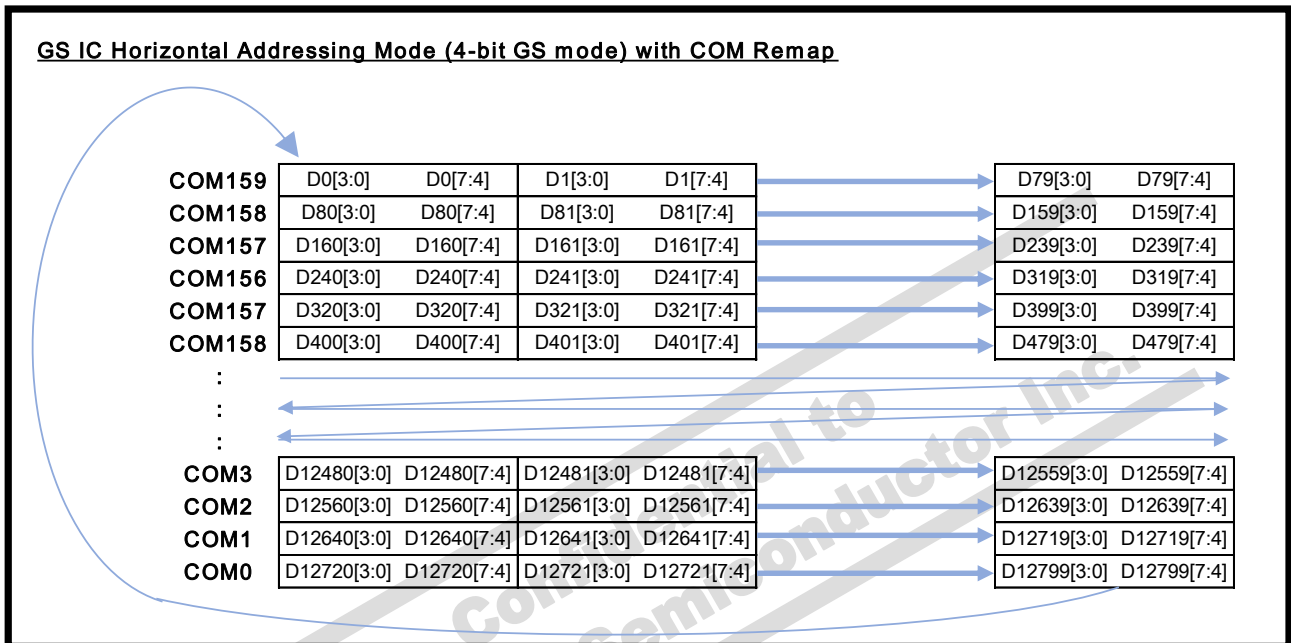
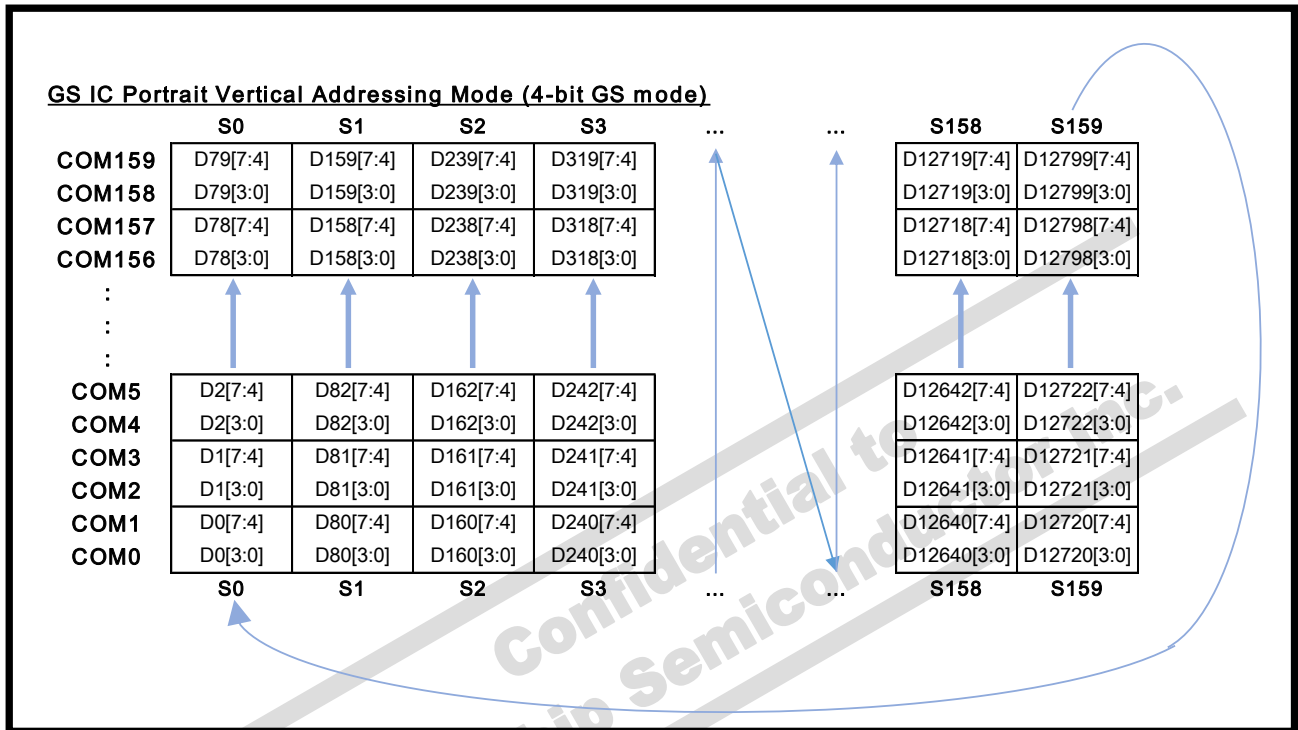


Table 6-10 shows the GDDRAM map under the following condition:

- Command Setting:
  - Disable Column Address Re-map   A0h
  - Vertical Address Increment       20h 01h
  - Disable COM Re-map               C0h
  - Enable Portrait Mode               25h 01h
- Display Start Line=00h
- Data byte sequence: D0, D1, D2 ... D12799

**Table 6-10 : GDDRAM address map 5**



## 6.8 SEG/COM Driving block

This block is used to derive the incoming power sources into the different levels of internal use voltage and current.

- $V_{CC}$  is the most positive voltage supply.
- $V_{COMH}$  is the Common deselected level. It is internally regulated.
- $V_{LSS}$  is the ground path of the analog and panel current.
- $I_{REF}$  is a reference current source for segment current drivers  $I_{SEG}$ . The relationship between reference current and segment current of a color is:

$$I_{SEG} = \text{Contrast} / 4 \times I_{REF}$$

in which the contrast (1~255) is set by Set Contrast command 81h

When internal  $I_{REF}$  is used, the  $I_{REF}$  pin should be kept NC.

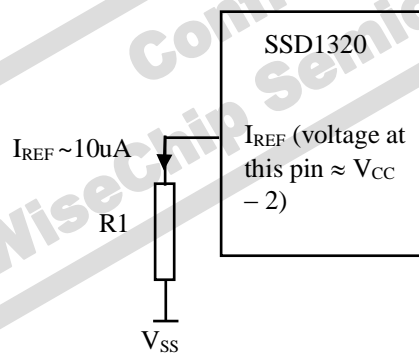
Bit A[4] of command ADh is used to select external or internal  $I_{REF}$  :

A[4] = '0' Select external  $I_{REF}$  [Reset]

A[4] = '1' Enable internal  $I_{REF}$  during display ON

When external  $I_{REF}$  is used, the magnitude of  $I_{REF}$  is controlled by the value of resistor, which is connected between  $I_{REF}$  pin and  $V_{SS}$  as shown in Figure 6-15 :  $I_{REF}$  Current Setting by Resistor Value. It is recommended to set  $I_{REF}$  to  $10 \pm 2\mu\text{A}$  so as to achieve  $I_{SEG} = 600\mu\text{A}$  at maximum contrast 255.

Figure 6-15 :  $I_{REF}$  Current Setting by Resistor Value



Since the voltage at  $I_{REF}$  pin is  $V_{CC} - 2\text{V}$ , the value of resistor R1 can be found as below:

For  $I_{REF} = 10\mu\text{A}$ ,  $V_{CC} = 12\text{V}$ :

$$\begin{aligned} R1 &= (\text{Voltage at } I_{REF} - V_{SS}) / I_{REF} \\ &\approx (12 - 2) / 10\mu\text{A} \\ &= 1\text{M}\Omega \end{aligned}$$

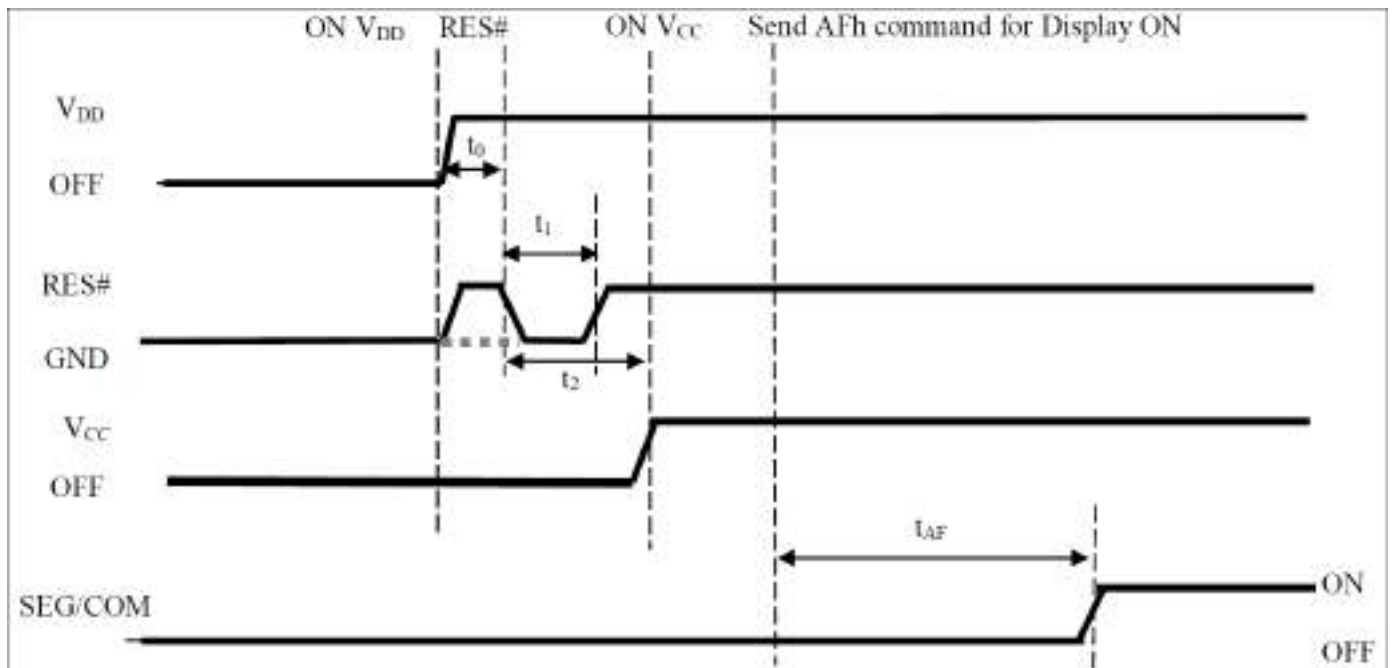
## 6.9 Power ON and OFF sequence

The following figures illustrate the recommended power ON and power OFF sequence of SSD1320.

*Power ON sequence:*

1. Power ON  $V_{DD}$
2. After  $V_{DD}$  become stable, wait at least 20ms ( $t_0$ ), set RES# pin LOW (logic low) for at least 3 $\mu$ s ( $t_1$ )<sup>(4)</sup> and then HIGH (logic high).
3. After set RES# pin LOW (logic low), wait for at least 3 $\mu$ s ( $t_2$ ). Then Power ON  $V_{CC}$ .<sup>(1)</sup>
4. After  $V_{CC}$  become stable, send command AFh for display ON. SEG/COM will be ON after 100ms ( $t_{AF}$ ).

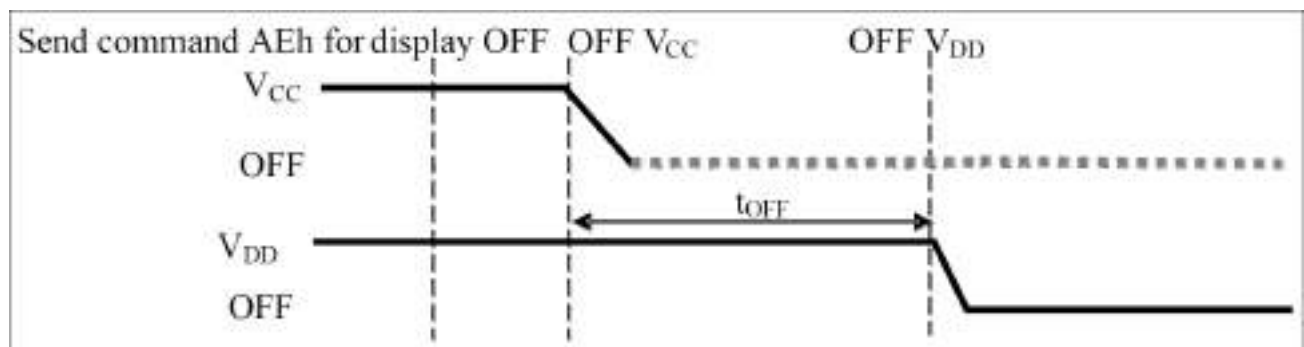
**Figure 6-16 : Power ON Sequence**



*Power OFF sequence:*

1. Send command AEh for display OFF.
2. Power OFF  $V_{CC}$ .<sup>(1), (2)</sup>
3. Power OFF  $V_{DD}$  after  $t_{OFF}$ .<sup>(4)</sup> (where Minimum  $t_{OFF}$ =0ms, typical  $t_{OFF}$ =100ms)

**Figure 6-17 : Power OFF Sequence**



**Note:**

- (1)  $V_{CC}$  should be kept float (i.e. disable) when it is OFF.
- (2) Power Pins ( $V_{DD}$ ,  $V_{CC}$ ) can never be pulled to ground under any circumstance.
- (3) The register values are reset after  $t_1$ .
- (4)  $V_{DD}$  should not be Power OFF before  $V_{CC}$  Power OFF.

## 7 MAXIMUM RATINGS

**Table 7-1 : Maximum Ratings**

(Voltage Reference to  $V_{SS}$ )

Symbol	Parameter	Value	Unit
$V_{DD}$	Supply Voltage	-0.3 to 4.0	V
$V_{CC}$		-0.5 to 19.0	V
$V_{SEG}$	SEG output voltage	0 to $V_{CC}$	V
$V_{COM}$	COM output voltage	0 to $0.9 \cdot V_{CC}$	V
$V_{in}$	Input voltage	$V_{SS}-0.3$ to $V_{DD}+0.3$	V
$T_A$	Operating Temperature	-40 to +85	°C
$T_{stg}$	Storage Temperature Range	-65 to +150	°C

\*Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the limits in the Electrical Characteristics tables or Pin Description.

\*This device may be light sensitive. Caution should be taken to avoid exposure of this device to any light source during normal operation. This device is not radiation protected.

Confidential to  
WiseChip Semiconductor Inc.

## 8 DC CHARACTERISTICS

### Condition (Unless otherwise specified):

Voltage referenced to  $V_{SS}$

$V_{DD} = 1.65V$  to  $3.5V$

$T_A = 25^\circ C$

Table 8-1 : DC Characteristics

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
$V_{CC}$	Operating Voltage	-	8	-	18	V
$V_{DD}$	Logic Supply Voltage	-	1.65	2.8	3.5	V
$V_{OH}$	High Logic Output Level	$I_{OUT} = 100\mu A, 10MHz$	$0.9 \times V_{DD}$	-	$V_{DD}$	V
$V_{OL}$	Low Logic Output Level	$I_{OUT} = 100\mu A, 10MHz$	0	-	$0.1 \times V_{DD}$	V
$V_{IH}$	High Logic Input Level	-	$0.8 \times V_{DD}$	-	$V_{DD}$	V
$V_{IL}$	Low Logic Input Level	-	0	-	$0.2 \times V_{DD}$	V
$I_{DD,SLEEP}$	Sleep mode Current	$V_{DD} = 1.65V \sim 3.5V, V_{CC} = 8V \sim 18V$ Display OFF, No panel attached	-	-	10	$\mu A$
$I_{CC,SLEEP}$	Sleep mode Current	$V_{DD} = 1.65V \sim 3.5V, V_{CC} = 8V \sim 18V$ Display OFF, No panel attached	-	-	10	$\mu A$
$I_{CC}$	$V_{CC}$ Supply Current $V_{DD} = 1.8V, V_{CC} = 15V,$ $I_{REF} = 10\mu A,$ No loading, Display ON, All ON	Contrast = FFh	-	980	1270	$\mu A$
$I_{DD}$	$V_{DD}$ Supply Current $V_{DD} = 1.8V, V_{CC} = 15V,$ $I_{REF} = 10\mu A,$ No loading, Display ON, All ON	Contrast = FFh	-	310	390	$\mu A$
$I_{SEG}$	Segment Output Current, $V_{DD} = 1.8V, V_{CC} = 15V,$ $I_{REF} = 10\mu A,$ Display ON.	Contrast=FFh	-	600	-	$\mu A$
		Contrast=7Fh	-	300	-	
		Contrast=3Fh	-	150	-	
$I_{SEG}$ Dev	Segment Output Current, $V_{DD} = 1.8V, V_{CC} = 15V,$ $I_{REF} = 10\mu A,$ Display ON. Segment output current uniformity	$Dev = (I_{SEG} - I_{MID}) / I_{MID}$ $I_{MID} = (I_{MAX} + I_{MIN}) / 2$ $I_{SEG}[0:159] =$ Segment current at contrast setting = FFh	-3	-	3	%
Adj. Dev	Adjacent pin output current uniformity (contrast setting = FFh)	$Adj\ Dev = (I[n] - I[n+1]) /$ $(I[n] + I[n+1])$	-2	-	2	%

## 9 AC CHARACTERISTICS

### Conditions:

Voltage referenced to  $V_{SS}$

$V_{DD}=1.65$  to  $3.5V$

$T_A = 25^{\circ}C$

**Table 9-1 : AC Characteristics**

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
$F_{OSC}^{(1)}$	Oscillation Frequency of Display Timing Generator	$V_{DD} = 1.8V$	2295	2550	2805	kHz
$F_{FRM}$	Frame Frequency	160x160 Graphic Display Mode, Display ON, Internal Oscillator Enabled	-	$F_{OSC} \times 1/(D \times K \times 160)^{(2)}$	-	Hz
RES#	Reset low pulse width		3	-	-	us

### Note

<sup>(1)</sup>  $F_{OSC}$  stands for the frequency value of the internal oscillator and the value is measured when command D5h is in default value.

<sup>(2)</sup> D: divide ratio (default value = 2)

K: number of display clocks per row period (default value = 75)

Please refer to (Set Display Clock Divide Ratio/Oscillator Frequency, D5h) for detailed description

Confidential to  
 WiseChip Semiconductor Inc.

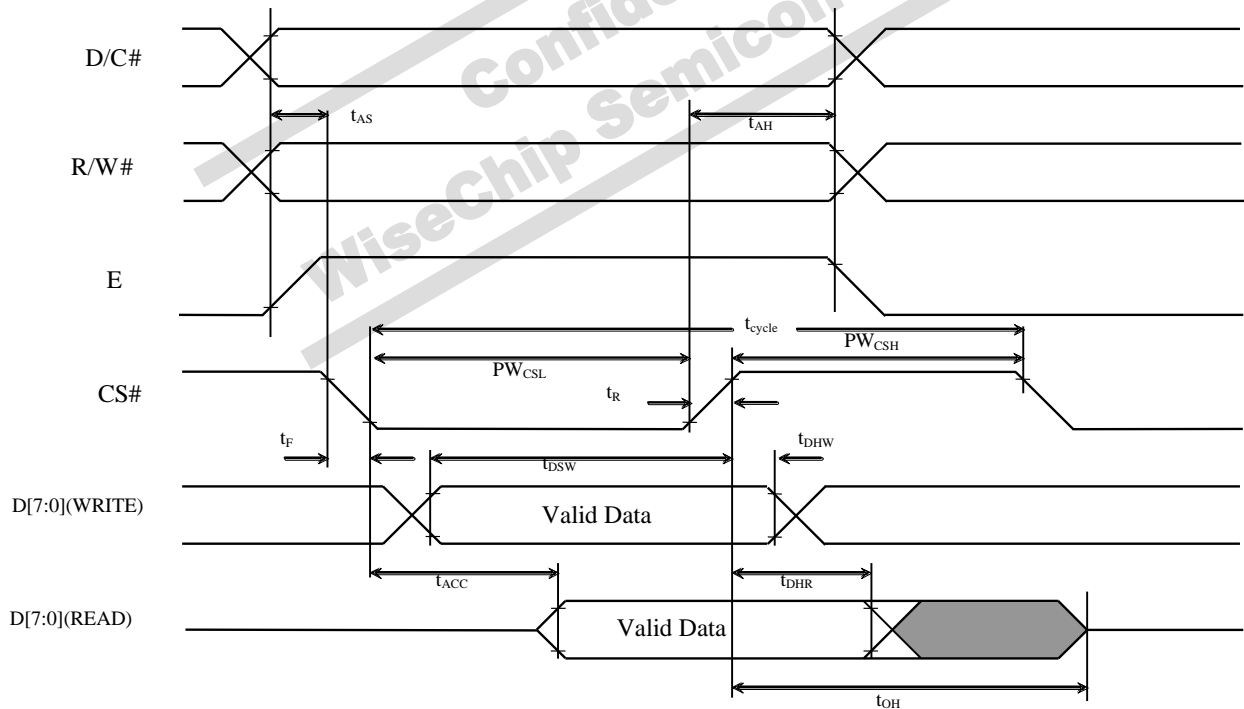


**Table 9-2 : 6800-Series MCU Parallel Interface Timing Characteristics**

( $V_{DD} - V_{SS} = 1.65V$  to  $3.5V$ ,  $T_A = 25^\circ C$ )

Symbol	Parameter	Min	Typ	Max	Unit
$t_{cycle}$	Clock Cycle Time	300	-	-	ns
$t_{AS}$	Address Setup Time	5	-	-	ns
$t_{AH}$	Address Hold Time	0	-	-	ns
$t_{DSW}$	Write Data Setup Time	40	-	-	ns
$t_{DHW}$	Write Data Hold Time	7	-	-	ns
$t_{DHR}$	Read Data Hold Time	20	-	-	ns
$t_{OH}$	Output Disable Time	-	-	70	ns
$t_{ACC}$	Access Time	-	-	140	ns
$PW_{CSL}$	Chip Select Low Pulse Width (read)	120	-	-	ns
	Chip Select Low Pulse Width (write)	60	-	-	ns
$PW_{CSH}$	Chip Select High Pulse Width (read)	60	-	-	ns
	Chip Select High Pulse Width (write)	60	-	-	ns
$t_R$	Rise Time	-	-	40	ns
$t_F$	Fall Time	-	-	40	ns

**Figure 9-1: 6800-series MCU parallel interface characteristics**

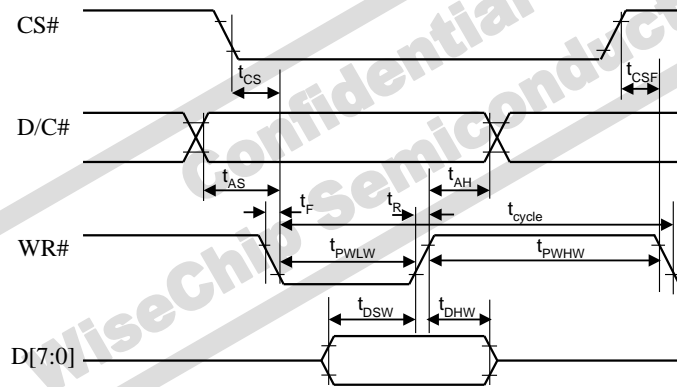


**Table 9-3 : 8080-Series MCU Parallel Interface Timing Characteristics**

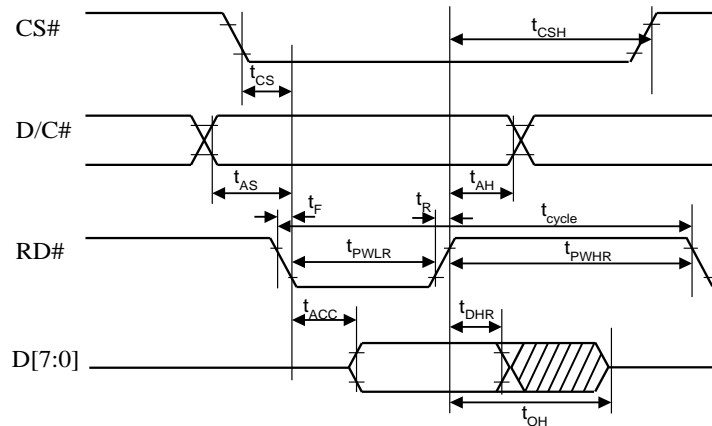
( $V_{DD} - V_{SS} = 1.65V \sim 3.5V$ ,  $T_A = 25^\circ C$ )

Symbol	Parameter	Min	Typ	Max	Unit
$t_{cycle}$	Clock Cycle Time	300	-	-	ns
$t_{AS}$	Address Setup Time	10	-	-	ns
$t_{AH}$	Address Hold Time	0	-	-	ns
$t_{DSW}$	Write Data Setup Time	40	-	-	ns
$t_{DHW}$	Write Data Hold Time	7	-	-	ns
$t_{DHR}$	Read Data Hold Time	20	-	-	ns
$t_{OH}$	Output Disable Time	-	-	70	ns
$t_{ACC}$	Access Time	-	-	140	ns
$t_{PWLR}$	Read Low Time	120	-	-	ns
$t_{PWLW}$	Write Low Time	60	-	-	ns
$t_{PWHR}$	Read High Time	60	-	-	ns
$t_{PWHW}$	Write High Time	60	-	-	ns
$t_R$	Rise Time	-	-	40	ns
$t_F$	Fall Time	-	-	40	ns
$t_{CS}$	Chip select setup time	0	-	-	ns
$t_{CSH}$	Chip select hold time to read signal	0	-	-	ns
$t_{CSF}$	Chip select hold time	20	-	-	ns

**Figure 9-2 : 8080-series parallel interface characteristics**



Write cycle



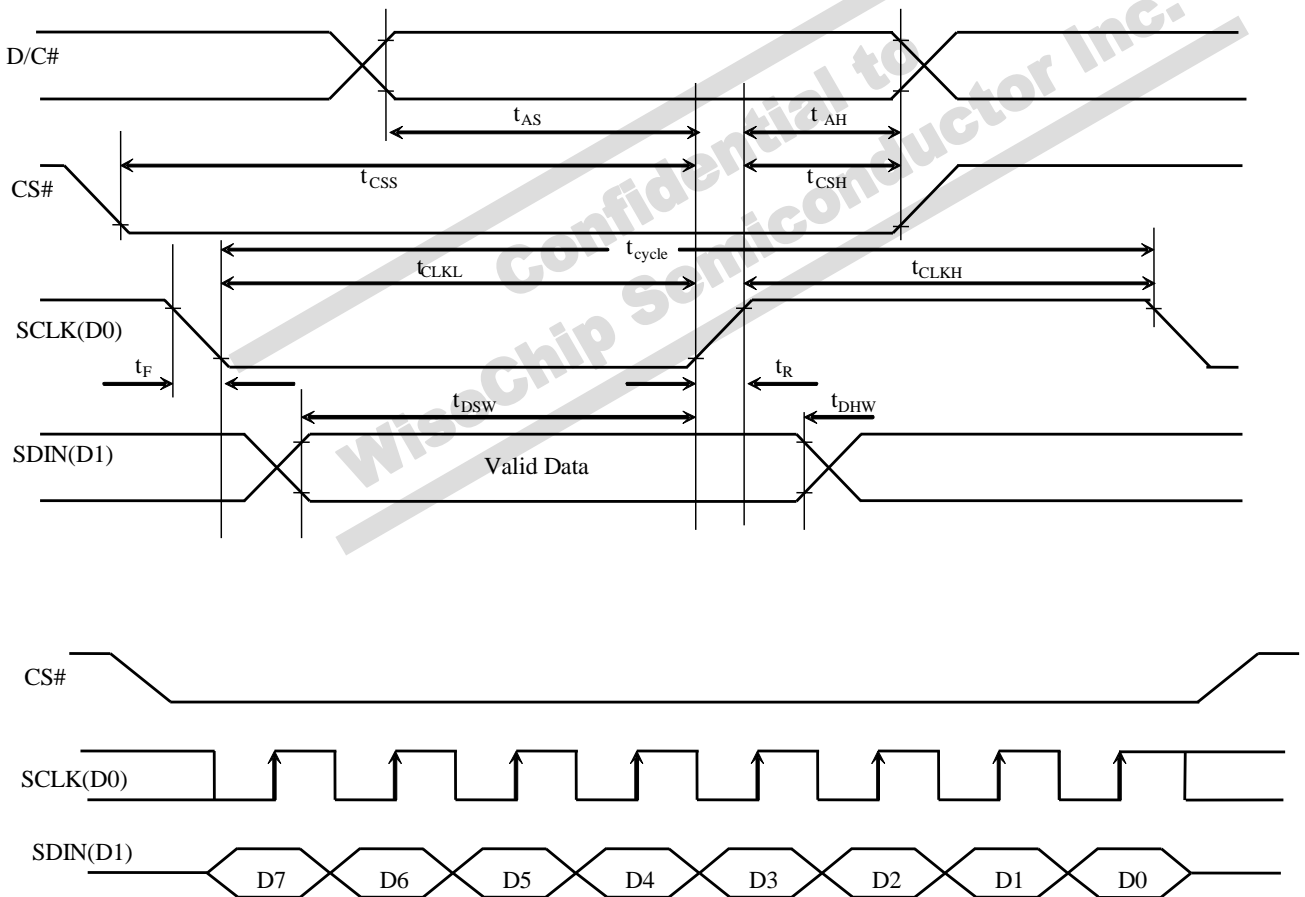
Read Cycle

**Table 9-4 : Serial Interface Timing Characteristics (4-wire SPI)**

( $V_{DD} - V_{SS} = 1.65V \sim 3.5V$ ,  $T_A = 25^\circ C$ )

Symbol	Parameter	Min	Typ	Max	Unit
$t_{cycle}$	Clock Cycle Time	66	-	-	ns
$t_{AS}$	Address Setup Time	15	-	-	ns
$t_{AH}$	Address Hold Time	15	-	-	ns
$t_{CSS}$	Chip Select Setup Time	20	-	-	ns
$t_{CSH}$	Chip Select Hold Time	10	-	-	ns
$t_{DSW}$	Write Data Setup Time	15	-	-	ns
$t_{DHW}$	Write Data Hold Time	15	-	-	ns
$t_{CLKL}$	Clock Low Time	20	-	-	ns
$t_{CLKH}$	Clock High Time	20	-	-	ns
$t_R$	Rise Time	-	-	15	ns
$t_F$	Fall Time	-	-	15	ns

**Figure 9-3 : Serial interface characteristics (4-wire SPI)**

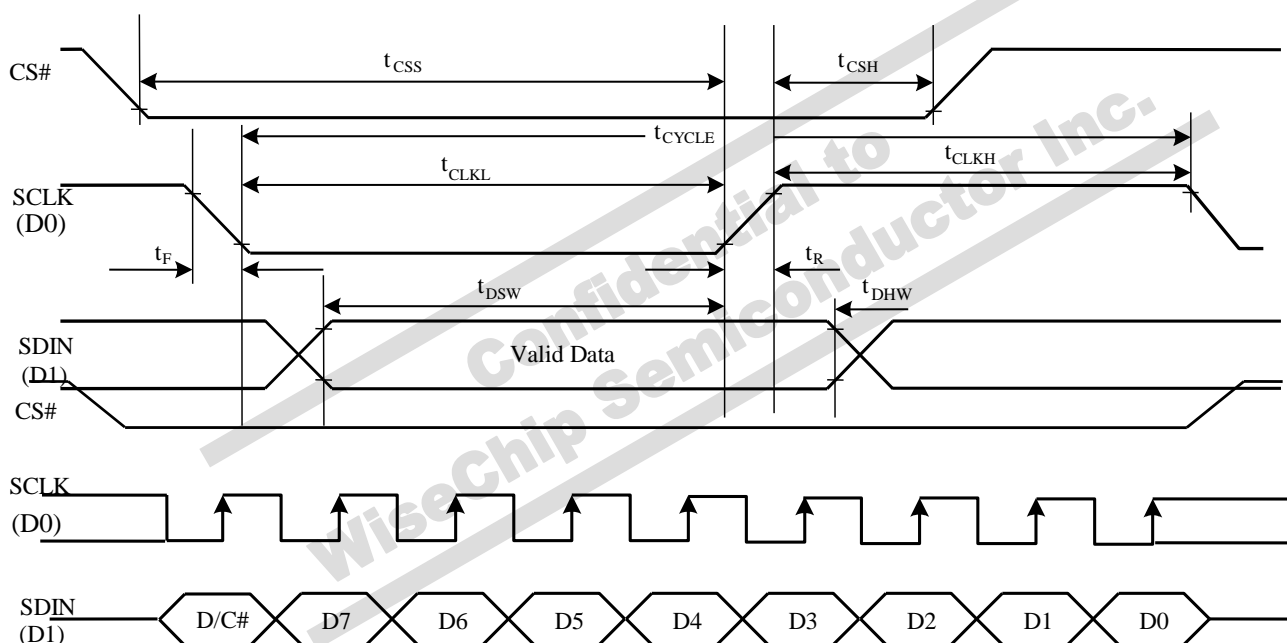


**Table 9-5 : Serial Interface Timing Characteristics (3-wire SPI)**

( $V_{DD} - V_{SS} = 1.65V \sim 3.5V$ ,  $T_A = 25^\circ C$ )

Symbol	Parameter	Min	Typ	Max	Unit
$t_{cycle}$	Clock Cycle Time	66	-	-	ns
$t_{CSS}$	Chip Select Setup Time	20	-	-	ns
$t_{CSH}$	Chip Select Hold Time	10	-	-	ns
$t_{DSW}$	Write Data Setup Time	15	-	-	ns
$t_{DHW}$	Write Data Hold Time	15	-	-	ns
$t_{CLKL}$	Clock Low Time	20	-	-	ns
$t_{CLKH}$	Clock High Time	20	-	-	ns
$t_R$	Rise Time	-	-	15	ns
$t_F$	Fall Time	-	-	15	ns

**Figure 9-4 : Serial interface characteristics (3-wire SPI)**

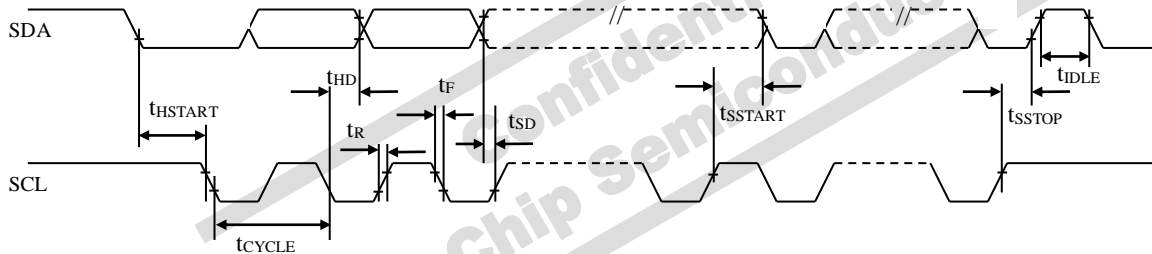


**Table 9-6 : I<sup>2</sup>C Interface Timing Characteristics**

(V<sub>DD</sub> - V<sub>SS</sub> = 1.65V~3.5V, T<sub>A</sub> = 25°C)

Symbol	Parameter	Min	Typ	Max	Unit
t <sub>cycle</sub>	Clock Cycle Time	2.5	-	-	us
t <sub>HSTART</sub>	Start condition Hold Time	0.6	-	-	us
t <sub>HD</sub>	Data Hold Time (for “SDA <sub>OUT</sub> ” pin)	0	-	-	ns
	Data Hold Time (for “SDA <sub>IN</sub> ” pin)	300	-	-	ns
t <sub>SD</sub>	Data Setup Time	100	-	-	ns
t <sub>SSTART</sub>	Start condition Setup Time (Only relevant for a repeated Start condition)	0.6	-	-	us
t <sub>SSTOP</sub>	Stop condition Setup Time	0.6	-	-	us
t <sub>R</sub>	Rise Time for data and clock pin	-	-	300	ns
t <sub>F</sub>	Fall Time for data and clock pin	-	-	300	ns
t <sub>IDLE</sub>	Idle Time before a new transmission can start	1.3	-	-	us

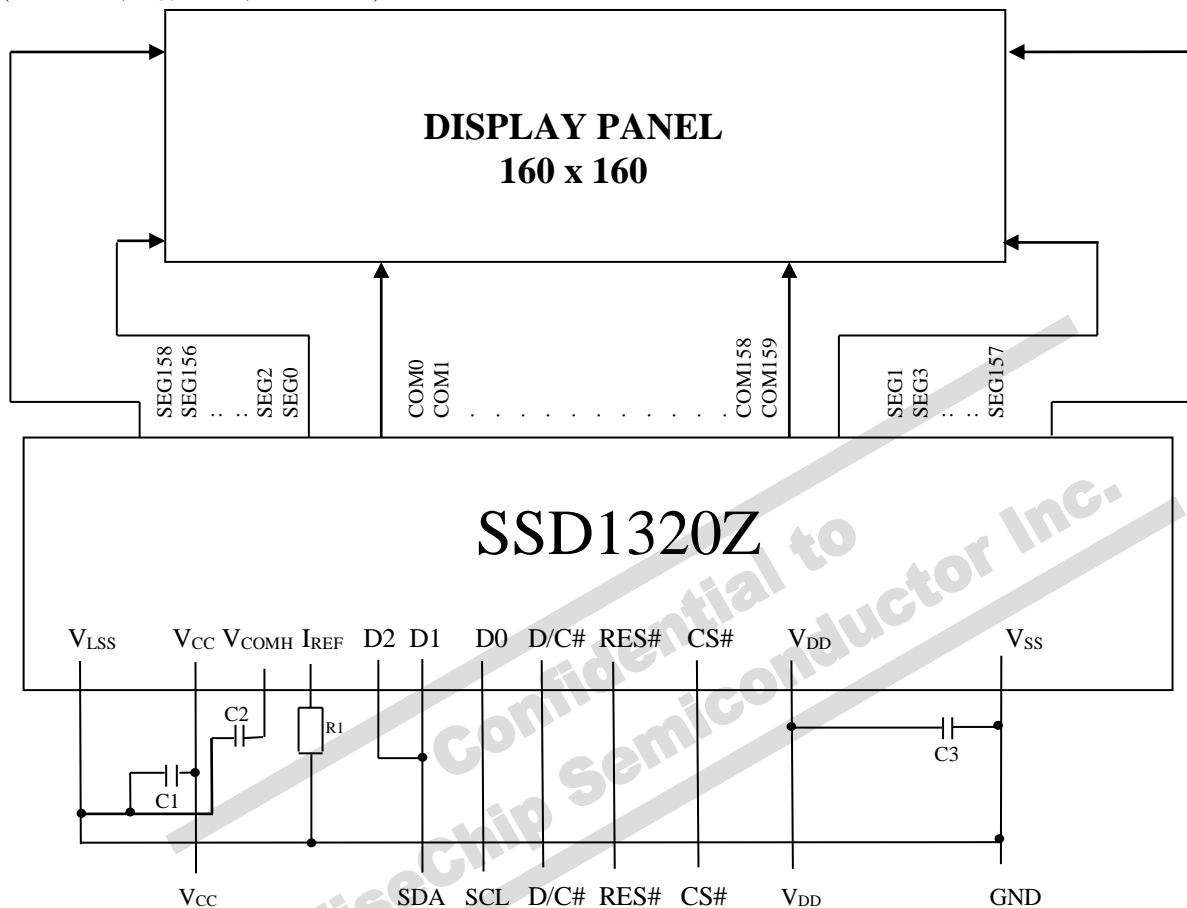
**Figure 9-5 : I<sup>2</sup>C interface Timing characteristics**



## 10 APPLICATION EXAMPLE

Figure 10-1 : Application Example of SSD1320Z

The configuration for 4-wire SPI interface mode is shown in the following diagram:  
 ( $V_{DD}=1.8V$ ,  $V_{CC}=15V$ ,  $I_{REF}=10\mu A$ )



Pin connected to MCU interface: D[2:0], RES#, D/C#, CS#

Pin internally connected to  $V_{LSS}$ : VSL

Pin internally connected to  $V_{SS}$  (or  $V_{LL}$ ): D[7:3], BS[2:0], E, R/W#, CL, BGGND

Pin internally connected to  $V_{DD}$  (or  $V_{LL}$ ): CLS

$V_{BREF}$ ,  $V_P$ , FR, T0, T1, TR[15:0], should be left open.

C1, C2: 2.2 $\mu F$  <sup>(1)</sup>

C3: 1.0 $\mu F$  <sup>(1)</sup> place close to IC  $V_{DD}$  and  $V_{SS}$  pins on PCB

Voltage at  $I_{REF} = V_{CC} - 2V$ . For  $V_{CC} = 15V$ ,  $I_{REF} = 10\mu A$ :

$$R1 = (Voltage\ at\ I_{REF} - V_{SS}) / I_{REF}$$

$$\approx (15-2)V / 10\mu A$$

$$\approx 1.3M\Omega$$

### Note

<sup>(1)</sup> The capacitor value is recommended value. Select appropriate value against module application.


<sup>(2)</sup> Die gold bump face down.

<sup>(3)</sup> All  $V_{LSS}$  pads of the IC are recommended to be connected together to form a larger area of GND.

<sup>(4)</sup>  $V_{LSS}$  and  $V_{SS}$  are not recommended to be connected on the ITO routing, but connected together in the PCB level at one common ground point for better grounding and noise insulation.

Confidential to  
WiseChip Semiconductor Inc.

Solomon Systech reserves the right to make changes without notice to any products herein. Solomon Systech makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Solomon Systech assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any, and all, liability, including without limitation consequential or incidental damages. “Typical” parameters can and do vary in different applications. All operating parameters, including “Typical” must be validated for each customer application by the customer’s technical experts. Solomon Systech does not convey any license under its patent rights nor the rights of others. Solomon Systech products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Solomon Systech product could create a situation where personal injury or death may occur. Should Buyer purchase or use Solomon Systech products for any such unintended or unauthorized application, Buyer shall indemnify and hold Solomon Systech and its offices, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Solomon Systech was negligent regarding the design or manufacture of the part.

 The product(s) listed in this datasheet comply with Directive 2011/65/EU of the European Parliament and of the council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment and People’s Republic of China Electronic Industry Standard GB/T 26572-2011 “Requirements for concentration limits for certain hazardous substances in electronic information products (电子电器产品中限用物質的限用要求)”. Hazardous Substances test report is available upon request.

<http://www.solomon-systech.com>